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NOTICE OF ALLOWANCE AND FEE(S) DUE

20985 7590 09/16/2005
FISH & RICHARDSON, PC
12390 EL CAMINO REAL
SAN DIEGO, CA 92130-2081

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EXAMINER

FREJD, RUSSELL WARREN

ART UNIT PAPER NUMBER

2128

DATE MAILED: 09/16/2005

| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|-----------------|-------------|----------------------|---------------------|------------------|
| 09/941,952 | 08/29/2001 | William R. Wheeler | 10559-597001 | 6372 |

TITLE OF INVENTION: SIMULATING A LOGIC DESIGN

| APPLN. TYPE | SMALL ENTITY | ISSUE FEE | PUBLICATION FEE | TOTAL FEE(S) DUE | DATE DUE |
|----------------|--------------|-----------|-----------------|------------------|------------|
| nonprovisional | NO | \$1400 | \$300 | \$1700 | 12/16/2005 |

THE APPLICATION IDENTIFIED ABOVE HAS BEEN EXAMINED AND IS ALLOWED FOR ISSUANCE AS A PATENT. **PROSECUTION ON THE MERITS IS CLOSED.** THIS NOTICE OF ALLOWANCE IS NOT A GRANT OF PATENT RIGHTS. THIS APPLICATION IS SUBJECT TO WITHDRAWAL FROM ISSUE AT THE INITIATIVE OF THE OFFICE OR UPON PETITION BY THE APPLICANT. SEE 37 CFR 1.313 AND MPEP 1308.

THE ISSUE FEE AND PUBLICATION FEE (IF REQUIRED) MUST BE PAID WITHIN **THREE MONTHS** FROM THE MAILING DATE OF THIS NOTICE OR THIS APPLICATION SHALL BE REGARDED AS ABANDONED. **THIS STATUTORY PERIOD CANNOT BE EXTENDED.** SEE 35 U.S.C. 151. THE ISSUE FEE DUE INDICATED ABOVE REFLECTS A CREDIT FOR ANY PREVIOUSLY PAID ISSUE FEE APPLIED IN THIS APPLICATION. THE PTOL-85B (OR AN EQUIVALENT) MUST BE RETURNED WITHIN THIS PERIOD EVEN IF NO FEE IS DUE OR THE APPLICATION WILL BE REGARDED AS ABANDONED.

HOW TO REPLY TO THIS NOTICE:

I. Review the SMALL ENTITY status shown above.

If the SMALL ENTITY is shown as YES, verify your current SMALL ENTITY status:

A. If the status is the same, pay the TOTAL FEE(S) DUE shown above.

B. If the status above is to be removed, check box 5b on Part B - Fee(s) Transmittal and pay the PUBLICATION FEE (if required) and twice the amount of the ISSUE FEE shown above, or

If the SMALL ENTITY is shown as NO:

A. Pay TOTAL FEE(S) DUE shown above, or

B. If applicant claimed SMALL ENTITY status before, or is now claiming SMALL ENTITY status, check box 5a on Part B - Fee(s) Transmittal and pay the PUBLICATION FEE (if required) and 1/2 the ISSUE FEE shown above.

II. PART B - FEE(S) TRANSMITTAL should be completed and returned to the United States Patent and Trademark Office (USPTO) with your ISSUE FEE and PUBLICATION FEE (if required). Even if the fee(s) have already been paid, Part B - Fee(s) Transmittal should be completed and returned. If you are charging the fee(s) to your deposit account, section "4b" of Part B - Fee(s) Transmittal should be completed and an extra copy of the form should be submitted.

III. All communications regarding this application must give the application number. Please direct all communications prior to issuance to Mail Stop ISSUE FEE unless advised to the contrary.

IMPORTANT REMINDER: Utility patents issuing on applications filed on or after Dec. 12, 1980 may require payment of maintenance fees. It is patentee's responsibility to ensure timely payment of maintenance fees when due.

PART B - FEE(S) TRANSMITTAL

Complete and send this form, together with applicable fee(s), to: **Mail**

**Mail Stop ISSUE FEE
Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450
(571) 273-2885**

or **Fax**

INSTRUCTIONS: This form should be used for transmitting the ISSUE FEE and PUBLICATION FEE (if required). Blocks 1 through 5 should be completed where appropriate. All further correspondence including the Patent, advance orders and notification of maintenance fees will be mailed to the current correspondence address as indicated unless corrected below or directed otherwise in Block 1, by (a) specifying a new correspondence address; and/or (b) indicating a separate "FEE ADDRESS" for maintenance fee notifications.

CURRENT CORRESPONDENCE ADDRESS (Note: Use Block 1 for any change of address)

20985 7590 09/16/2005

**FISH & RICHARDSON, PC
12390 EL CAMINO REAL
SAN DIEGO, CA 92130-2081**

Note: A certificate of mailing can only be used for domestic mailings of the Fee(s) Transmittal. This certificate cannot be used for any other accompanying papers. Each additional paper, such as an assignment or formal drawing, must have its own certificate of mailing or transmission.

Certificate of Mailing or Transmission

I hereby certify that this Fee(s) Transmittal is being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to the Mail Stop ISSUE FEE address above, or being facsimile transmitted to the USPTO (571) 273-2885, on the date indicated below.

| |
|--------------------|
| (Depositor's name) |
| (Signature) |
| (Date) |

| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|-----------------|-------------|----------------------|---------------------|------------------|
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|----------------|--------------|-----------|-----------------|------------------|------------|
| nonprovisional | NO | \$1400 | \$300 | \$1700 | 12/16/2005 |

| EXAMINER | ART UNIT | CLASS-SUBCLASS |
|-----------------------|----------|----------------|
| FREJD, RUSSELL WARREN | 2128 | 703-015000 |

1. Change of correspondence address or indication of "Fee Address" (37 CFR 1.363).

- ☐ Change of correspondence address (or Change of Correspondence Address form PTO/SB/122) attached.
- ☐ "Fee Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Customer Number is required.

2. For printing on the patent front page, list

- (1) the names of up to 3 registered patent attorneys or agents OR, alternatively,
- (2) the name of a single firm (having as a member a registered attorney or agent) and the names of up to 2 registered patent attorneys or agents. If no name is listed, no name will be printed.

| | |
|---|-------|
| 1 | _____ |
| 2 | _____ |
| 3 | _____ |

3. ASSIGNEE NAME AND RESIDENCE DATA TO BE PRINTED ON THE PATENT (print or type)

PLEASE NOTE: Unless an assignee is identified below, no assignee data will appear on the patent. If an assignee is identified below, the document has been filed for recordation as set forth in 37 CFR 3.11. Completion of this form is NOT a substitute for filing an assignment.

(A) NAME OF ASSIGNEE

(B) RESIDENCE: (CITY and STATE OR COUNTRY)

Please check the appropriate assignee category or categories (will not be printed on the patent): ☐ Individual ☐ Corporation or other private group entity ☐ Government

4a. The following fee(s) are enclosed:

- ☐ Issue Fee
- ☐ Publication Fee (No small entity discount permitted)
- ☐ Advance Order - # of Copies _____

4b. Payment of Fee(s):

- ☐ A check in the amount of the fee(s) is enclosed.
- ☐ Payment by credit card. Form PTO-2038 is attached.
- ☐ The Director is hereby authorized by charge the required fee(s), or credit any overpayment, to Deposit Account Number _____ (enclose an extra copy of this form).

5. Change in Entity Status (from status indicated above)

- ☐ a. Applicant claims SMALL ENTITY status. See 37 CFR 1.27. ☐ b. Applicant is no longer claiming SMALL ENTITY status. See 37 CFR 1.27(g)(2).

The Director of the USPTO is requested to apply the Issue Fee and Publication Fee (if any) or to re-apply any previously paid issue fee to the application identified above. NOTE: The Issue Fee and Publication Fee (if required) will not be accepted from anyone other than the applicant; a registered attorney or agent; or the assignee or other party in interest as shown by the records of the United States Patent and Trademark Office.

Authorized Signature _____

Date _____

Typed or printed name _____

Registration No. _____

This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

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| 20985 | 7590 | 09/16/2005 | | |
| FISH & RICHARDSON, PC 12390 EL CAMINO REAL SAN DIEGO, CA 92130-2081 | | | | |
| | | | EXAMINER FREJD, RUSSELL WARREN | |
| | | | ART UNIT 2128 | PAPER NUMBER |
| DATE MAILED: 09/16/2005 | | | | |

Determination of Patent Term Adjustment under 35 U.S.C. 154 (b) (application filed on or after May 29, 2000)

The Patent Term Adjustment to date is 682 day(s). If the issue fee is paid on the date that is three months after the mailing date of this notice and the patent issues on the Tuesday before the date that is 28 weeks (six and a half months) after the mailing date of this notice, the Patent Term Adjustment will be 682 day(s).

If a Continued Prosecution Application (CPA) was filed in the above-identified application, the filing date that determines Patent Term Adjustment is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retrieval (PAIR) WEB site (<http://pair.uspto.gov>).

Any questions regarding the Patent Term Extension or Adjustment determination should be directed to the Office of Patent Legal Administration at (571) 272-7702. Questions relating to issue and publication fee payments should be directed to the Customer Service Center of the Office of Patent Publication at (703) 305-8283.

Notice of Allowability

Application No.

09/941,952

Examiner

Russell Frejd

Applicant(s)

WHEELER ET AL.

Art Unit

2128

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address--

All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. **THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS.** This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.

1. ☒ This communication is responsive to applicant's amendment received 23-May-2005.
2. ☒ The allowed claim(s) is/are 1-5,7-15,17-25 and 27-30.
3. ☒ The drawings filed on 28 January 2003 are accepted by the Examiner.
4. ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 - a) ☐ All b) ☐ Some* c) ☐ None of the:
 1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)).

* Certified copies not received: _____.

Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.
THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.

5. ☐ A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.
 6. ☐ CORRECTED DRAWINGS (as "replacement sheets") must be submitted.
 - (a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached
 - 1) ☐ hereto or 2) ☐ to Paper No./Mail Date _____.
 - (b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date _____.
- Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).
7. ☐ DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.

Attachment(s)

1. ☒ Notice of References Cited (PTO-892)
2. ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
3. ☒ Information Disclosure Statements (PTO-1449 or PTO/SB/08), Paper No./Mail Date 7.20.05
4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material
5. ☐ Notice of Informal Patent Application (PTO-152)
6. ☐ Interview Summary (PTO-413), Paper No./Mail Date _____
7. ☐ Examiner's Amendment/Comment
8. ☒ Examiner's Statement of Reasons for Allowance
9. ☐ Other _____

Russell Frejd
RUSSELL FREJD
PRIMARY EXAMINER

In re Application of: Wheeler et al.

Allowance of Application # 09/941,952

1. The following communication is in response to applicant's amendment received 23-May-2005, and applicant's IDS received on 20-July-2005.

Reasons for Allowance

2. The following is an Examiner's Statement of Reasons for the indication of allowable subject matter. The instant application is directed to a non-obvious improvement over the invention described in U.S. Patent No. 5,220,512, the improvement comprising an apparatus and method for simulating a logic design comprised of combinatorial logic and state logic, wherein clock domains are identified for combinatorial logic and state logic using separate graphic elements, computer code is generated based on the clock domains that simulate operation of portions of the logic design, and the computer code is associated with the graphic elements. This patentable distinction is included in each of the independent claims, nos. 1, 11, and 21. The art of record, either individually or in combination, fails to teach, suggest, or render obvious the useful, concrete and tangible <simulation of a logic design comprised of combinatorial logic and state logic strength> having the corresponding structure which is disclosed in the specification and equivalents thereof at least at page 2, line 17 through page 17, line 4, and Figures 1-7. In view of the foregoing, the claims of the present application are found to be patentable over the prior art.

Response Guidelines

3. Any comments considered necessary by applicant **MUST** be submitted no later than the payment of the Issue Fee and, to avoid processing delays, should preferably accompany the

In re Application of: Wheeler et al.

Issue Fee. Such submissions should clearly be labeled "Comments on Statement of Reasons for Allowance".

3.1 Any response to the Examiner in regard to this allowance should be

directed to: Russell Frejd, telephone number (571) 272-3779, Monday-Friday from 0530 to 1400 ET, or the examiner's supervisor, Jean Homere, telephone number (571) 272-3780. Inquires of a general nature or relating to the status of this application should be directed to the TC2100 Group Receptionist (571) 272-2100.

mailed to: Commissioner of Patents and Trademarks
P.O. Box 1450, Alexandria, VA 22313-1450

or faxed to: (571) 273-8300

Hand-delivered responses should be brought to the Customer Service Window, Randolph Building, 401 Dulany Street, Alexandria, VA, 22314.

Date: 8-August-2005



**RUSSELL FREJD
PRIMARY EXAMINER**

From IDS on 3.15.04

Sheet 1 of 4

| | | | |
|--|--|--|--------------------------------------|
| Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b)) | U.S. Department of Commerce Patent and Trademark Office | Attorney's Docket No. 10559-597001 | Application No. 09/941,952 |
| | Applicant William R. Wheeler et al. | | |
| | Filing Date August 29, 2001 | Group Art Unit 2123 | |

| U.S. Patent Documents | | | | | | | |
|-----------------------|-----------|-----------------|------------------|----------------------|-------|----------|----------------------------|
| Examiner Initial | Desig. ID | Document Number | Publication Date | Patentee | Class | Subclass | Filing Date If Appropriate |
| M.S. | AA | RE 38,059 | 04/2003 | Yano, et al. | | | |
| | AB | 4,703,435 | 10/1987 | Darringer, et al. | | | |
| | AC | 4,970,664 | 11/1990 | Kaiser, et al. | | | |
| | AD | 5,212,650 | 05/1993 | Hooper, et al. | | | |
| | AE | 5,267,175 | 11/1993 | Hooper | | | |
| | AF | 5,278,769 | 01/1994 | Bair, et al. | | | |
| | AG | 5,287,289 | 02/1994 | Kageyama, et al. | | | |
| | AH | 5,297,053 | 03/1994 | Pease, et al. | | | |
| | AI | 5,301,318 | 04/1994 | Mittal | | | |
| | AJ | 5,384,710 | 01/1995 | Lam, et al. | | | |
| | AK | 5,475,605 | 12/1995 | Lin | | | |
| | AL | 5,493,507 | 02/1996 | Shinde, et al. | | | |
| | AM | 5,544,067 | 08/1996 | Rostoker, et al. | | | |
| | AN | 5,568,397 | 10/1996 | Yamashita, et al. | | | |
| | AO | 5,598,347 | 01/1997 | Iwasaki | | | |
| | AP | 5,603,015 | 02/1997 | Kurosawa, et al. | | | |
| | AQ | 5,604,894 | 02/1997 | Pickens, et al. | | | |
| | AR | 5,663,662 | 09/1997 | Kurosawa | | | |
| | AS | 5,673,198 | 09/1997 | Lawman, et al. | | | |
| | AT | 5,685,006 | 11/1997 | Shiraishi | | | |
| | AU | 5,694,579 | 12/1997 | Razdan, et al. | | | |
| | AV | 5,706,476 | 01/1998 | Giramma | | | |
| | AW | 5,717,928 | 02/1998 | Campmas, et al. | | | |
| | AX | 5,724,250 | 03/1998 | Kerzman, et al. | | | |
| | AY | 5,757,655 | 05/1998 | Shih, et al. | | | |
| | AZ | 5,809,283 | 09/1998 | Vaidyanathan, et al. | | | |
| ✓ | AAA | 5,831,869 | 11/1998 | Ellis, et al. | | | |

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|--|---------------------------|
| Examiner Signature <i>William Wheeler</i> | Date Considered 1/9/05 |
| EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | |

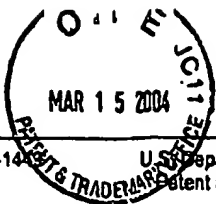
IDS 3.15.04

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|--|--|--|--|-------------------------------|
| Substitute Form PTO 1449 (Modified) | | U.S. Department of Commerce Patent and Trademark Office | Attorney's Docket No. 10559-597001 | Application No. 09/941,952 |
| Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b)) | | | Applicant William R. Wheeler et al. | |
| | | | Filing Date August 29, 2001 | Group Art Unit 2123 |

| Patent Documents | | | | | | | |
|------------------|-----------|-----------------|------------------|-------------------|-------|----------|----------------------------|
| Examiner Initial | Desig. ID | Document Number | Publication Date | Patentee | Class | Subclass | Filing Date If Appropriate |
| M.S. | ABB | 5,841,663 | 11/1998 | Sharma, et al. | | | |
| | ACC | 5,892,682 | 04/1999 | Hasley, et al. | | | |
| | ADD | 5,903,469 | 05/1999 | Ho | | | |
| | AEE | 5,937,190 | 08/1999 | Gregory, et al. | | | |
| | AFF | 5,974,242 | 10/1999 | Damarla, et al. | | | |
| | AGG | 6,077,304 | 06/2000 | Kasuya | | | |
| | AHH | 6,161,211 | 12/2000 | Southgate | | | |
| | AII | 6,178,541 | 01/2001 | Joly, et al. | | | |
| | AJJ | 6,208,954 | 03/2001 | Houtchens | | | |
| | AKK | 6,216,256 | 04/2001 | Inoue, et al. | | | |
| | ALL | 6,226,780 | 05/2001 | Bahra, et al. | | | |
| | AMM | 6,234,658 | 05/2001 | Houldsworth | | | |
| | ANN | 6,275,973 | 08/2001 | Wein | | | |
| | AOO | 6,292,931 | 09/2001 | Dupenloup | | | |
| | APP | 6,327,693 | 12/2001 | Cheng, et al. | | | |
| | AQQ | 6,353,806 | 03/2002 | Gehlot | | | |
| | ARR | 6,353,915 | 03/2002 | Deal, et al. | | | |
| | ASS | 6,360,356 | 03/2002 | Eng | | | |
| | ATT | 6,381,563 | 04/2002 | O'Riordan, et al. | | | |
| | AUU | 6,381,565 | 04/2002 | Nakamura | | | |
| | AVV | 6,421,816 | 07/2002 | Ishikura | | | |
| | AWW | 6,438,729 | 08/2002 | Ho | | | |
| | AXX | 6,438,731 | 08/2002 | Segal | | | |
| | AYY | 6,440,780 | 08/2002 | Kimura, et al. | | | |
| | AZZ | 6,473,885 | 10/2002 | Wallace | | | |
| | AAAA | 6,477,688 | 11/2002 | Wallace | | | |
| | ABBB | 6,490,545 | 12/2002 | Peng | | | |

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|--|----------------------------|
| Examiner Signature <i>Murray Swannet</i> | Date Considered 11/9/05 |
| EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | |



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Sheet 3 of 4

| | | | |
|---|--|--|--------------------------------------|
| Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b)) | U.S. Department of Commerce Patent and Trademark Office | Attorney's Docket No. 10559-597001 | Application No. 09/941,952 |
| | Applicant William R. Wheeler et al. | | |
| | Filing Date August 29, 2001 | Group Art Unit 2123 | |

| U.S. Patent Documents | | | | | | | |
|-----------------------|-----------|-----------------|------------------|----------------------|-------|----------|----------------------------|
| Examiner Initial | Desig. ID | Document Number | Publication Date | Patentee | Class | Subclass | Filing Date If Appropriate |
| MS | ACCC | 6,505,328 | 01/2003 | Van Ginneken, et al. | | | |
| | ADDD | 6,516,456 | 02/2003 | Garnett, et al. | | | |
| | AEEE | 6,519,742 | 02/2003 | Falk | | | |
| | AFFF | 6,523,156 | 02/2003 | Cirit | | | |
| | AGGG | 6,539,536 | 03/2003 | Singh et al. | | | |
| | AHHH | 6,546,528 | 04/2003 | Sasaki, et al. | | | |
| | AIHH | 6,574,787 | 06/2003 | Anderson | | | |
| | AJJJ | 6,591,407 | 07/2003 | Kaufman, et al. | | | |
| | AKKK | 2002/0038447 | 03/2002 | Kim, et al. | | | |
| | ALLL | 2002/0059054 | 05/2002 | Bade, et al. | | | |
| | AMMM | 2002/0112221 | 08/2002 | Ferreri, et al. | | | |
| | ANNN | 2002/0138244 | 09/2002 | Meyer | | | |
| | AOOO | 2003/0004699 | 01/2003 | Choi, et al. | | | |
| | APPP | 2003/0036871 | 02/2003 | Fuller, et al. | | | |
| | AQQQ | 2003/0177455 | 09/2003 | Kaufman, et al. | | | |

| Foreign Patent Documents or Published Foreign Patent Applications | | | | | | | | |
|---|-----------|-----------------|------------------|--------------------------|-------|----------|-------------|----|
| Examiner Initial | Desig. ID | Document Number | Publication Date | Country or Patent Office | Class | Subclass | Translation | |
| | | | | | | | Yes | No |
| MS | ARRR | 0 404 482 | 12/1990 | EPO | | | | |
| | ASSS | 0 720 233 | 07/1996 | EPO | | | | |
| | ATTT | 58-060559 | 04/1983 | Japan | | | | |
| | AUUU | 03-225523 | 10/1991 | Japan | | | | |
| | AVVV | 07-049890 | 02/1995 | Japan | | | | |
| | AWWW | 08-314892 | 11/1996 | Japan | | | | |
| | AXXX | 2001-068994 | 03/2001 | Japan | | | | |
| | AYYY | WO 98/37475 | 08/1998 | WIPO | | | | |
| | AZZZ | WO 98/55879 | 12/1998 | WIPO | | | | |

| | |
|--|----------------------------------|
| Examiner Signature <i>Michael Sheehan</i> | Date Considered <i>1/9/05</i> |
| EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | |

Substitute Disclosure Form (PTO-1449)



IDS 3.15.04

Sheet 4 of 4

| | | | |
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| | Applicant William R. Wheeler et al. | | |
| | Filing Date August 29, 2001 | Group Art Unit 2123 | MAR 17 2004 |

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| Foreign Patent Documents or Published Foreign Patent Applications | | | | | | | | |
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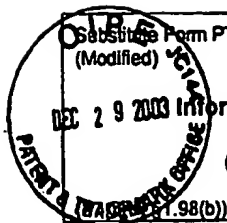
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Sheet 1 of 1



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(Modified)

U.S. Department of Commerce
Patent and Trademark Office

Attorney's Docket No.
10559-597001

Application No.
09/941,952

Information Disclosure Statement
by Applicant
(Use several sheets if necessary)

Applicant
William R. Wheeler et al.

Filing Date
August 29, 2001

Group Art Unit
2123

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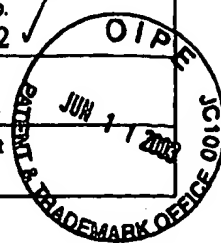
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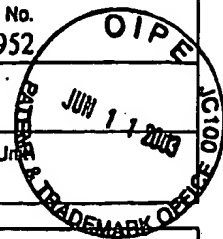
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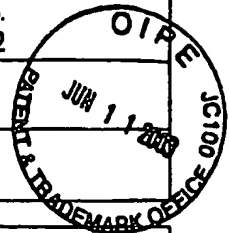
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DESIGN DIVERSITY FOR CONCURRENT ERROR DETECTION IN SEQUENTIAL LOGIC CIRCUITS

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Abstract

We present a technique using diverse duplication to implement concurrent error detection (CED) in sequential logic circuits. We examine three different approaches for this purpose: (1) Identical state encoding of the two sequential logic implementations, duplication of flip-flops, diverse implementation of the combinational logic part (output logic and next-state logic) and comparators on flip-flop outputs and primary outputs; (2) Diverse state encoding of the two implementations, duplication of flip-flops, diverse combinational logic implementation and comparators on primary outputs only; and (3) Identical state encoding, parity prediction for the flip-flops, diverse combinational logic implementation, comparators on primary outputs and parity checkers on flip-flop outputs. Our results for the simulated sequential benchmark circuits demonstrate that the third approach is most efficient in protecting sequential logic circuits against multiple and common-mode failures. The computational complexity of the data integrity analysis of the third approach is of the same order as that of the first approach and is at least an order of magnitude less than that of the second approach.

1. Introduction

Concurrent Error Detection (CED) techniques are widely used for designing systems with high data integrity. By data integrity, we mean that the system either produces correct outputs or generates an error signal when incorrect outputs are produced. A duplex system in the form of a self-checking pair is a classical example of a CED scheme which has been used for guaranteeing data integrity in many applications like the IBM G5 and G6 processors [Spainhower 99]. Figure 1.1 shows the basic principle of operation of a duplex system. As long as only one module fails, a duplex system provides guaranteed data integrity.

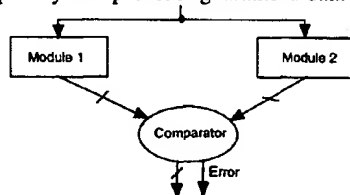


Figure 1.1. A duplex redundant system

It is generally assumed that module failures are independent events; hence, in a duplex system, the probability that both modules fail is very low for realistic failure rates. However, this assumption is not always true. In a duplex system, *common-mode failures* (CMFs) result from failures that affect both modules at the same time, generally due to a common cause [Lala 94]. These include operational failures due to external (such as EMI, power-supply disturbances, radiation) or internal causes and design mistakes. CMFs are surveyed in [Mitra 00a].

Design diversity was proposed and used in the past to protect redundant systems against common-mode failures [Avizienis 84, Briere 93, Riter 95]. In [Avizienis 84], design diversity was defined as the independent generation of two or more software or hardware elements (e.g., program modules, VLSI circuit masks, etc.) to satisfy a given requirement. The basic idea is that, with different implementations, common failure modes will cause different error effects.

The conventional notion of diversity is qualitative and does not provide any quantitative insight into design of diverse duplex systems. In [Mitra 99a], a metric was developed to quantify design diversity and analyze the reliability, availability and data integrity of duplex systems using this metric. In [Mitra 00b], this metric was used as a cost function to synthesize diverse implementations of combinational logic functions. However, the efforts on characterization of diverse duplex systems were focused on combinational logic circuits. In this paper, we extend our ideas to sequential logic circuits.

This work was done as part of the ROAR (Reliability Obtained by Adaptive Reconfiguration) project [Saxena 00]. In the project, the system under consideration is reconfigurable and contains user-programmable logic elements (e.g., FPGAs). For such systems, faults can be detected during system operation, the faulty part can be located, and the system can be reconfigured to operate without using the defective part. The Field Replaceable Unit (FRU) is a programmable logic block or a routing resource, instead of a chip or a board used in any conventional fault-tolerant system. Hence, it is reasonable to design combinational or sequential logic with concurrent error detection such as duplication.

In Sec. 2, we describe three approaches to designing sequential logic circuits with CED based on diverse

duplication and present simulation results comparing these three schemes. Section 3 describes a technique to analyze the data integrity of sequential logic circuits with CED. We conclude in Sec. 4.

2. Diverse Duplication for Sequential Logic Circuits

We consider the Finite State Machine (FSM) model of sequential circuits [McCluskey 86] as shown in Fig. 2.1. In addition, we assume that faults do not affect the clock signal (not shown in Fig. 2.1) in the FSM implementations. While our technique can be extended for faults on clock signal lines, this assumption is reasonable when fault-tolerant clocks [Siewiorek 92] are used.

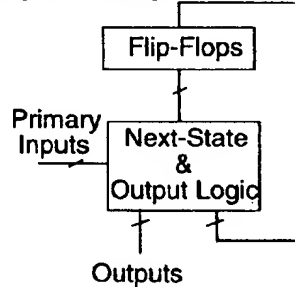


Figure 2.1. FSM model of a sequential circuit

Various techniques have been proposed in the past to implement concurrent error detection in sequential circuits. These include techniques based on parity prediction, Berger and Bose-Lin codes. [Zeng 99] presents a comprehensive description of these previously reported CED techniques for sequential logic circuits. Results presented in [Mitra 00c] demonstrate that, for general combinational logic circuits, CED techniques based on diverse duplication provide better protection against multiple failures and CMFs compared to simple duplication and parity prediction; moreover, the area overhead of diverse duplication is comparable to (or marginally more than) that of parity prediction. Hence, in this paper we study CED techniques based on diverse duplication for sequential logic circuits.

2.1. Identical State Encoding and Diverse Logic (ISEDL)

In Fig. 2.2 both implementations have identical encoding of the FSM internal states; however, we have diverse implementations of the next-state and the output logic. The primary outputs and the state-bits (flip-flop outputs) of the two implementations are compared and an error is indicated when a mismatch occurs.

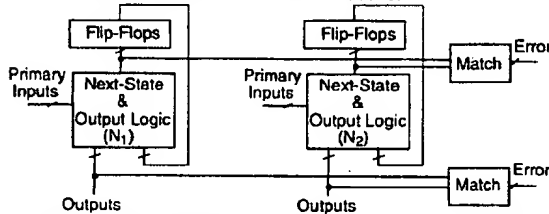


Figure 2.2. Identical state encoding and diverse logic (ISEDL)

For synthesizing diverse implementations of the next-state and the output logic the technique in [Mitra 00b] can be used. This CED technique suffers from the problem that there is no diversity in the state encoding (i.e., the flip-flop contents). In the worst-case, for a fault f affecting a flip-flop in the first implementation, a fault g affecting the corresponding flip-flop in the second implementation can be identified, such that the fault pair (f, g) can never be detected by the comparator; this situation is not desirable.

2.2. Diverse State Encoding and Diverse Logic (DSEDL)

Diversity can be created by encoding the internal states of the given FSM in "different" ways in the two implementations. This provides another degree of freedom in the synthesis of FSMs with CED based on diverse duplication and can possibly help in providing enhanced protection against CMFs compared to the scheme in Fig. 2.2. This scheme is shown in Figure 2.3. Since the encoding of the internal states of the FSM are not identical in the two implementations, simple self-checking comparator designs cannot be used to check the flip-flop outputs – the comparator design can be very complex. This can degrade the capability of this technique to detect multiple failures and CMFs.

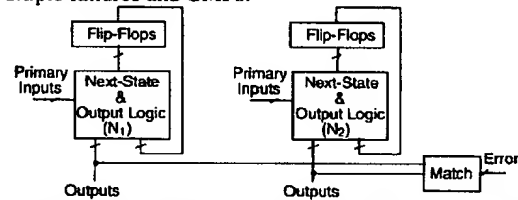


Figure 2.3. Diverse state encoding and logic implementation (DSEDL)

The encoding of the internal states of the second implementation can be looked upon as a transformation of the encoding of the internal states of the first implementation. Formally, if $E_1(s)$ represents the encoding of state s in the first implementation, and $E_2(s)$ represents the encoding of state s in the second implementation, then $E_2(s) = T(E_1(s))$. If T is a "simple" transformation (e.g., linear transformation consisting of xor gates only), then we can design inexpensive checkers (e.g., parity trees) to check the flip-flop outputs.

2.3. Diverse Duplication for Output Logic; Parity Prediction for Next-State Logic (PPNSLDOL & PPDOL)

The CED technique ISEDL (Sec. 2.1) has the following advantages over the technique DSEDL (Sec. 2.2): (1) The flip-flop outputs in the two implementations can be compared; hence, if a fault-pair produces non-identical next state outputs, it will be detected; (2) As will be illustrated in Sec. 3, the computational complexity of the analysis of the ISEDL technique is much less than that of the DSEDL technique. However, the ISEDL technique suffers from the problem of having no diversity in the flip-flop contents.

The CED scheme of this section combines the advantages of the ISEDL and DSEDL techniques. We use diverse duplication for the output logic and parity prediction for the next-state logic of the FSM implementation. Figures 2.4a and 2.4b show two implementations of this CED scheme.

In Fig. 2.4a we use simple parity prediction for the next-state logic (with the appropriate constraints on logic sharing). The technique in [Mitra 00b] can be used for synthesizing the diverse implementations of the output logic; the technique in [Touba 97] can be used for synthesizing the next-state logic with parity prediction. This technique is called PPNSDOL (Parity Prediction for Next State Logic and Diverse Output Logic).

In Fig. 2.4b, we use diverse duplication for the next state logic also and check the outputs of the two implementations using a comparator. Then, we add one or more parity trees at the outputs of one of these implementations to generate parity bits. This technique is called PPDL (Parity Prediction and Diverse Logic). The PPDL technique provides more protection from multiple failures and CMFs affecting the next-state logic compared to the PPNSDOL technique (Fig. 2.4a) [Mitra 00a].

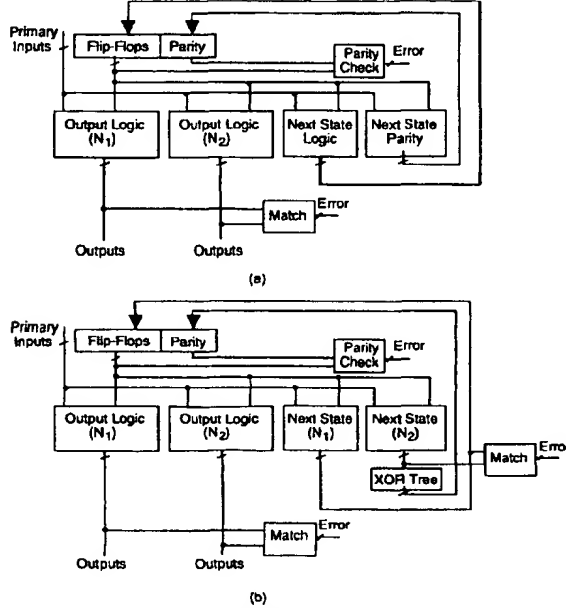


Figure 2.4. Diverse Duplication of sequential logic circuits with parity prediction on flip-flops. (a) PPNSDOL (b) PPDL.

2.4. Simulation Results

In Table 2.1 we report the area overhead of the CED schemes for some MCNC FSM benchmark circuits and the IEEE 1149.1 Boundary-Scan TAP controller [Parker 92] (named TAP).

The circuits were synthesized using the *Sis* tool [Sentovich 92]. For synthesizing diverse implementations of the FSM next-state and output logic we synthesized truth

tables with true and complemented outputs using the *Sis* tool. We used *espresso* for two-level minimization, *rugged.script* for multi-level optimization and the LSI Logic G10p library [LSI 96] for technology mapping. For synthesizing FSMs with diverse state encoding, we used two different state encoding algorithms *nova* [Villa 90] and *jedi* [Lin 89]. For synthesizing parity prediction for next-state logic we used the technique described in [Touba 97]. For most cases, the PPDL technique (Fig. 2.4b) generates circuits with less area overhead compared to PPNSDOL (Fig. 2.4a); hence, area results for the PPNSDOL technique are not shown in Table 2.1.

Table 2.1. Area Results (LSI G10p Units)

| Circuit Name | Comb. Logic area, # Flip-Flops | | |
|--------------|--------------------------------|----------|---------|
| | ISEDL | DSEDL | PPDL |
| TAP | 371, 8 | 406, 8 | 390, 5 |
| bbsse | 801, 8 | 780, 8 | 841, 5 |
| cse | 1159, 8 | 1127, 8 | 1195, 5 |
| beecount | 197, 6 | 208, 6 | 222, 4 |
| dk14 | 506, 6 | 559, 6 | 526, 4 |
| ex1 | 1654, 10 | 1639, 10 | 1704, 6 |

Next, we present simulation results on the vulnerability of CED techniques to multiple failures and CMFs. In dependable systems, it is realistic to assume that a corrective action is initiated after the system generates an error signal. Thus, for any system with CED, data integrity is guaranteed as long as the system does not produce an undetected corrupt output before indicating an error.

For each fault pair (f_i, f_j) affecting the FSM, for each primary input sequence, the FSM produces outputs that belong to the following categories: (1) correct outputs; (2) produces an error signal before producing an undetected erroneous output; (3) produces an undetected erroneous output before producing an error signal. Let $y_{i,j}$ be the fraction of input sequences for which the system produces only correct outputs; let $z_{i,j}$ be the fraction of input sequences for which the system produces an error signal before producing an undetected erroneous output. We

define the term $w_{i,j} = \frac{z_{i,j}}{1 - y_{i,j}}$ for the fault pair (f_i, f_j) as

the detected fraction or incorrect output detectability, which is the fraction of primary input sequences producing erroneous outputs for which the system data integrity is maintained. If the value of this term is 1 the system either produces correct outputs or indicates erroneous situations when incorrect outputs are produced. If the value is 0 the system never produces any error signal when incorrect outputs are produced. Note that, if a CED-based system produces correct outputs for all input combinations even in the presence of a fault, then the fault is redundant. Similarly, for each fault pair (f_i, f_j) , we define the probability of undetected error as $x_{i,j} = 1 - y_{i,j} - z_{i,j}$.

We used the following simulation procedure. For each single-stuck-at fault f_i , we simulated exhaustively all fault

pairs to identify another single-stuck-at fault f_j in the same circuit that had the minimum value of $w_{i,j}$ or $x_{i,j}$. Hence, the fault pair (f_i, f_j) can be regarded as a *worst-case fault pair*. Finally, we averaged the $w_{i,j}$'s (or $x_{i,j}$'s) over all the worst-case fault pairs. The primary input sequences during simulation were applied in the following way. For each state s of the implemented FSM, we initialized the FSM to state s and applied 500-1000 pseudo-random primary input sequences generated by an LFSR; each primary input sequence was of length of 100-200. The results for fault pairs in the combinational logic parts are shown in Table 2.2. The benchmark circuits are small enough so that the simulation procedure can be completed. For Table 2.2, the results for the CED techniques PPNSDOL and PDDL (Fig. 2.4a and 2.4b) are not shown separately because the results for PDDL (Fig. 2.4b) are the same as that for ISEDL (Fig. 2.2). Moreover, as discussed in [Mitra 00c], the results for PPNSDOL are worse than that for PDDL.

Table 2.2. Worst-case analysis of faults in comb. logic

| Circuit Name | Incorr. O/p Detectability | | Prob. Undet. Error | |
|--------------|---------------------------|-------|--------------------|-------|
| | ISEDL, PDDL | DSEDL | ISEDL, PDDL | DSEDL |
| TAP | 0.4 | 0.06 | 0.6 | 0.94 |
| beecount | 0.33 | 0.37 | 0.38 | 0.33 |
| cse | 0.46 | 0.46 | 0.11 | 0.12 |
| dk14 | 0.54 | 0.54 | 0.34 | 0.38 |

The results of Table 2.2 indicate that, for the simulated designs, the protection provided by the ISEDL or PDDL techniques against multiple failures or CMFs in the combinational logic is better than or comparable to that of the DSEDL technique (diverse state encoding). The DSEDL technique has very low incorrect output detectability for the TAP controller FSM. This is mainly due to the fact that, for the DSEDL technique, the combinational logic can produce non-identical errors on the flip-flop inputs; however, since there is no "easy way" to check the flip-flop contents, these errors cannot be detected and eventually the faults eventually produce identical errors. Table 2.3 shows simulation results for faults affecting only the flip-flop outputs.

Table 2.3. Worst-case analysis of faults on flip-flops

| Circuit Name | Incorr. O/p Detectability | | | Prob. Undet. Error | |
|--------------|---------------------------|--------|---------------|--------------------|---------------|
| | ISE DL | DSE DL | PPNSDOL, PDDL | DSE DL | PPNSDOL, PDDL |
| TAP | 0 | 0.74 | 0.54 | 0.26 | 0.46 |
| cse | 0 | 0.30 | 0.43 | 0.14 | 0.34 |
| dk14 | 0 | 0.40 | 0.49 | 0.6 | 0.51 |
| dk16 | 0 | 0.48 | 0.54 | 0.52 | 0.46 |
| ex1 | 0 | 0.58 | 0.48 | 0.42 | 0.52 |

The results of Table 2.2 and 2.3 demonstrate the effectiveness of the PDDL technique of Fig. 2.4b (diverse combinational logic implementation, parity prediction for flip-flops and generation of parity bit through an XOR-tree from a next-state logic implementation) for implementing CED in the simulated designs.

It may be noted here that, if transient faults create bit-flips (rather than bit-stucks) in the flip-flops of a sequential circuit, then the CED technique based on diverse state

encoding technique based on linear transformations, which is an extension of the idea of parity prediction as described at the end of Sec. 2.2, is expected to outperform the other techniques (ISEDL, PPNSDOL or PDDL) so far as data integrity is concerned.

In the next section we describe a formal technique for analyzing each of the CED schemes; the discussion also shows that the computational complexity of analyzing the DSEDL technique is at least an order of magnitude higher than that of the ISEDL, PPNSDOL or PDDL techniques.

3. Analysis of CED schemes

Suppose that we are given two implementations N_1 and N_2 of an FSM M . The FSM M can be characterized by a state table [McCluskey 86] which can be formally represented by the following set $\{I, O, S, T, L\}$. Here, I is the set of primary input combinations, O is the set of primary output combinations and S is the set of internal states. T is the transition logic which can be looked upon as a mapping from $S \times I$ to S . L is the output logic which can be represented as a mapping from $S \times I$. An input distribution of an FSM is given by the conditional probability distribution $P(i|s)$ for all $i \in I$ and $s \in S$. $P(i|s)$ is the conditional probability that a primary input combination $i \in I$ is applied to the FSM when it is in state s . For the current paper, we assume that all primary input combinations are equally likely for all states. However, for specific systems, the input distribution can be approximated using trace simulations.

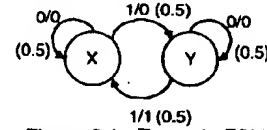


Figure 3.1. Example FSM

For example, consider the example FSM in Fig. 3.1. For this FSM, $S = \{X, Y\}$; $I = \{0, 1\}$, $O = \{0, 1\}$. The next-state logic T is given by: $T(X, 0) = X$, $T(X, 1) = Y$, $T(Y, 0) = Y$ and $T(Y, 1) = X$. The output logic L is: $L(X, 0) = 0$, $L(X, 1) = 0$, $L(Y, 0) = 0$ and $L(Y, 1) = 1$. For any state, the probability that the primary input has value 0 (or 1) is 0.5. Figures 3.2a and 3.2b show two implementations N_1 and N_2 of the FSM in Fig. 3.1. If we use these two implementations for CED we have a DSEDL CED technique.

Let us suppose that faults f and g affect implementations N_1 and N_2 , respectively. We can construct faulty FSMs $M_f = \{I, O, S_f, T_f, L_f\}$ and $M_g = \{I, O, S_g, T_g, L_g\}$ in the presence of f and g , respectively. The two faulty FSMs are shown in Fig. 3.2c and 3.2d, respectively. Next, we can construct the product machine $K = M \times M_f \times M_g$, as follows. The set of states of K is given by $K_S = S \times S_f \times S_g$; i.e., each state of K can be represented as a tuple (a, b, c) , where $a \in S$, $b \in S_f$ and $c \in S_g$. The transition logic K_T of K is given by the following mapping: $K_T((a, b, c))$

c), i] = $[T(a, i), T_f(b, i), T_g(c, i)]$ where $(a, b, c) \in S \times S_f \times S_g$ and $i \in I$. The output logic K_L of the product FSM K is a mapping from $K_S \times I$ to $O \times O \times O$ and is defined by $K_L[(a, b, c), i] = [L(a, i), L_f(b, i), L_g(c, i)]$ where $(a, b, c) \in S \times S_f \times S_g$ and $i \in I$. The input distribution of the product FSM K is defined as $P[i|(a, b, c)] = P[i|a]$ in FSM M , where $(a, b, c) \in S \times S_f \times S_g$ and $i \in I$. Figure 3.3 shows the product FSM K for the example in Fig. 3.2.

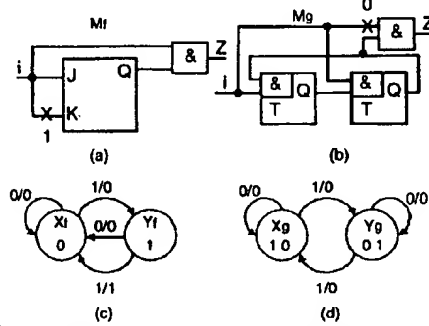


Figure 3.2. FSM implementations with faults. (a) Implementation with fault f. (b) Implementation with fault g. (c)-(d) State diagram of implementation with fault f and g.

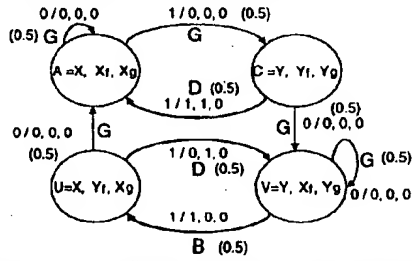


Figure 3.3. Product FSM: Good, Bad, Detecting transitions

The state transitions of the product FSM K can be classified into following categories: (1) *good* (G) transition, (2) *detecting* (D) transition, and (3) *bad* (B) transition.

A transition from state (a, b, c) under input combination i is a *good transition* if the output produced by the FSM M is the same as the outputs produced by M_f and M_g . Formally, a transition $K_T[(a, b, c), i] = [T(a, i), T_f(b, i), T_g(c, i)]$ is a good transition if and only if $L(a, i) = L_f(b, i) = L_g(c, i)$.

A transition from state (a, b, c) under input combination i is a *detecting transition* if the outputs produced by M_f and M_g are different. Formally, a transition $K_T[(a, b, c), i] = [T(a, i), T_f(b, i), T_g(c, i)]$ is a detecting transition if and only if $L_f(b, i) \neq L_g(c, i)$.

A transition from state (a, b, c) under input combination i is a *bad transition* if M_f and M_g produce identical erroneous outputs (different from the output produced by M). Formally, a transition $K_T[(a, b, c), i] =$

$[T(a, i), T_f(b, i), T_g(c, i)]$ is a bad transition if and only if $L(a, i) \neq L_f(b, i)$ and $L_f(b, i) = L_g(c, i)$.

Figure 3.3 shows the labels of the transitions of the product FSM K . For a CED technique based on diverse logic implementation but identical state encoding, the outputs of the corresponding flip-flops in the two implementations can be compared. This means that any state (a, b, c) in the product machine K detects the presence of a fault if $b \neq c$. All such states can be merged into a single state *Detected*. This reduction is not possible for a CED scheme with diverse state encoding unless there is an "easy" way to check that both the implementations are in the same state. All detecting transitions in the product machine K can be redirected to the *Detected* state; all edges starting from the states that are merged into the *Detected* state can be deleted. There is no outgoing edge from the *Detected* state. All bad transitions in the product FSM K can be redirected to a new state *Error*. There is no outgoing edge from the *Error* state. After these reductions, all unreachable states and edges starting from them in the final FSM can be deleted. Figure 3.4 illustrates these reduction techniques for the product FSM in Fig. 3.3 for the case when the internal states of the two FSMs are checked. The system never enters an *Error* state and the data integrity in the presence of the fault pair is 1.

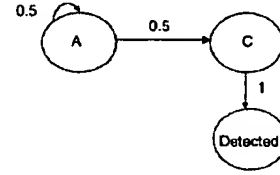


Figure 3.4. Reduced FSM with comparator states

The data integrity of the CED system at time t in the presence of faults can be defined in the following way. For each state s of the original fault-free FSM, we identify the state $S = (a, b, c)$ in the product FSM such that $a = s$, and b and c are the corresponding the states in the two implementations with faults; next, we calculate the probability $E(S, t)$ of being in the *Error* state in the product FSM at time t starting from state S . This can be calculated using straightforward Markov analysis techniques and tools like SHARPE (<http://www.ee.duke.edu/~kst>). The data integrity of the CED system in the presence of a given fault pair is equal to $\sum_s P(s)[1 - E(S, t)]$. Here, $P(s)$ is the

stationary probability of state s in the original fault-free FSM. For very low failure rates, it is realistic to assume that the original FSM reaches a stationary probability state before a fault affects the FSM. Analysis of CED schemes based on diverse duplication of output logic and parity prediction of next-state logic is similar to the analysis technique described above and is not repeated.

3.1. Computational Complexity of the Analysis

Theoretically, the above analysis technique is computationally intensive because of the following problems. The analysis technique may run into memory problems due to possible state space explosion during the computation of the product FSM. For example, if the original FSM has 64 states, it is theoretically possible that the product FSM will have $64^3 = 262,144$ states if we use the DSEDL technique (without comparators comparing the flip-flop outputs). Moreover, if the original FSM has a large number of primary inputs, then the construction of the product FSM will be very time consuming if we have to compute the state transition of the product FSM from each state for each primary input combination. In Table 3.1, we show the characteristics of the 1149.1 Boundary-Scan TAP controller and the MCNC FSM benchmark circuits and the average and the maximum number of states in the product FSM over all single stuck-at fault pairs.

Most of the FSM benchmarks in the MCNC benchmark suite have the number of states not more than 32. The TAP FSM has 16 states and a single primary input. A similar observation can be made about the internal benchmark FSM specifications of CAD companies. This is perhaps because FSMs used in real designs are designed as interacting state machines.

Table 3.1. Characteristics of designs for which exact analysis of ISEDL, PPNSDOL and PDDL is feasible

| Circuit Name | # PI, # PO, # States | Avg. # states in product FSM | Max. # states in product FSM |
|--------------|----------------------|------------------------------|------------------------------|
| TAP | 1, 7, 16 | 22 | 90 |
| cse | 7, 7, 16 | 23 | 140 |
| dk16 | 2, 3, 27 | 45 | 342 |
| ex1 | 9, 19, 18 | 25 | 160 |
| sand | 11, 9, 32 | 60 | 600 |

However, there are some FSM specifications with the number of states approximately 97 or 135; moreover, for FSMs with a large number of primary inputs, an exact analysis for each input combination can be very time consuming (FSMs *s420*, *s510*, *s820* and *scf* with 19, 19, 18 and 27 primary inputs, respectively). For these FSM benchmarks approximate techniques must be devised.

4. Conclusions

We studied the problem of implementing concurrent error detection (CED) based on diverse duplication in sequential logic circuits. We examined three different techniques for this purpose. Our simulation results demonstrate that the CED technique based on diverse duplication of combinational logic and parity prediction of flip-flop contents is most efficient in protecting sequential logic circuits against multiple and common-mode failures. We also described an exact technique to analyze the data integrity of sequential logic circuits with CED. Our results on MCNC benchmark circuits show that the exact analysis technique is feasible for many (80 %) benchmark circuits although theoretically it can suffer from state space explosion problems. Future research must focus on extending the idea of parity prediction for next-state logic

to generate "simple" transformations for diverse state encoding and developing efficient analysis techniques that do not suffer from state explosion problems and can handle FSM specifications with a large number of primary inputs.

5. Acknowledgments

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Monte Carlo Optimization of Superconducting Complementary Output Switching Logic Circuits

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Abstract—The authors have previously proposed a new superconducting voltage-state logic family called complementary output switching logic (COSL). This logic family has been designed using a Monte Carlo optimization process such that circuits have a high theoretical yield at 5–10 Gb/s clock speeds in spite of existing Josephson process variations. In the present work the Monte Carlo optimization process is described and theoretical yields are calculated for the COSL 2- and 3-bit encoder circuits. The circuit simulations use 5–10-GHz sinusoidal clocks and measured global and local process variations. The 2-bit encoder results are compared to modified variable threshold logic (MVTL) circuits and demonstrate that COSL circuits should have a significantly higher theoretical yield than MVTL at 10 Gb/s. Design rules for optimal COSL circuit layouts are also given, and experimental data are presented for 2-bit encoder circuits operating at multigigahertz clock frequencies. HSPICE is used for all Monte Carlo simulations and the Josephson junction model is given in the Appendix.

Index Terms—Monte Carlo methods, superconducting device testing, superconducting integrated circuits, yield optimization.

I. INTRODUCTION

PRACTICAL applications of superconducting logic will require digital circuits that can operate at 10-Gb/s clock speeds and beyond. Unfortunately, Josephson circuits are especially sensitive to process variations and, in the case of voltage-state logic, increasing clock speeds beyond 2 Gb/s tends to seriously degrade circuit margins [1]. We have proposed a new type of voltage-state logic called complementary output switching logic (COSL) [2], [3]. These circuits were optimized for 5–10-Gb/s operation using a Monte Carlo method so that they are relatively robust to process variations. In the present work the Monte Carlo optimization method is described in detail and is applied to 2- and 3-bit encoder circuits for a flash analog-to-digital converter (ADC).

A number of factors combine to make reaching the goal of 10-Gb/s superconducting circuits challenging. At a fundamental level the primary roadblocks have been flux trapping and process variations. Trapped flux in or near Josephson junctions significantly depresses junction critical currents and can, by reducing the overall circuit margins, prevent large

circuits from operating. We have previously studied the flux trapping problem in detail and demonstrated that with good shielding and moats one can practically eliminate flux trapping in the Josephson circuits [4]. Process variations can also significantly reduce circuit margins and can prevent large digital circuits from operating correctly [5], [6]. We have, therefore, developed a circuit optimization method which explicitly includes process variations.

We combine experimental measurements on process spreads with Monte Carlo simulations. The COSL gates are optimized using a Monte Carlo method, and we iterate between basic gates and complex circuits to optimize the yield of large circuits. Simulation examples are given for 2- and 3-bit encoder circuits, and experimental test results for 2-bit encoder circuits operating at 1–4 Gb/s are presented. Design rules for optimal COSL circuit design are also discussed. The simulations demonstrate that COSL circuits should have a significantly higher theoretical yield than modified variable threshold logic (MVTL) circuits [7], [8] in the clock frequency range 5–10 GHz. Note that while we specifically apply Monte Carlo optimization to voltage-state logic, the optimization technique is also applicable to rapid single flux quantum (RSFQ) circuits [9]–[11].

We review the basic COSL gates in the following section. Section III describes experimental testing results to determine 3σ local process variations in critical current and resistance, and the basic Monte Carlo optimization method is described. Two examples are given in Section IV: 2-bit and 3-bit encoders for fully parallel flash ADC's. The 2-bit encoder is compared to a similar MVTL encoder, and yields from Monte Carlo calculations are given for various process spreads. Design rules, circuit layouts, and experimental test results are described in Section V, and a summary and conclusion are given in Section VI. The HSPICE model used for the simulations is listed in the Appendix.

II. REVIEW OF COSL GATES

We first briefly review the basic ideas of the COSL family [2], [3]. Fig. 1(a) shows the OR/AND gate, and Fig. 1(b) the NOR/NAND gate. The XOR function is derived from the OR gate by including a 300- μ A Josephson junction in series with the inputs, Fig. 1(a). All of the gates consist of a one-junction SQUID input stage and a two-junction SQUID output stage [12]. The two-junction SQUID in the output stage is connected in series with a Josephson junction. The COSL circuits are designed to use a three-phase sinusoidal clocking scheme, and the input and output stages of the gates use two of the clock

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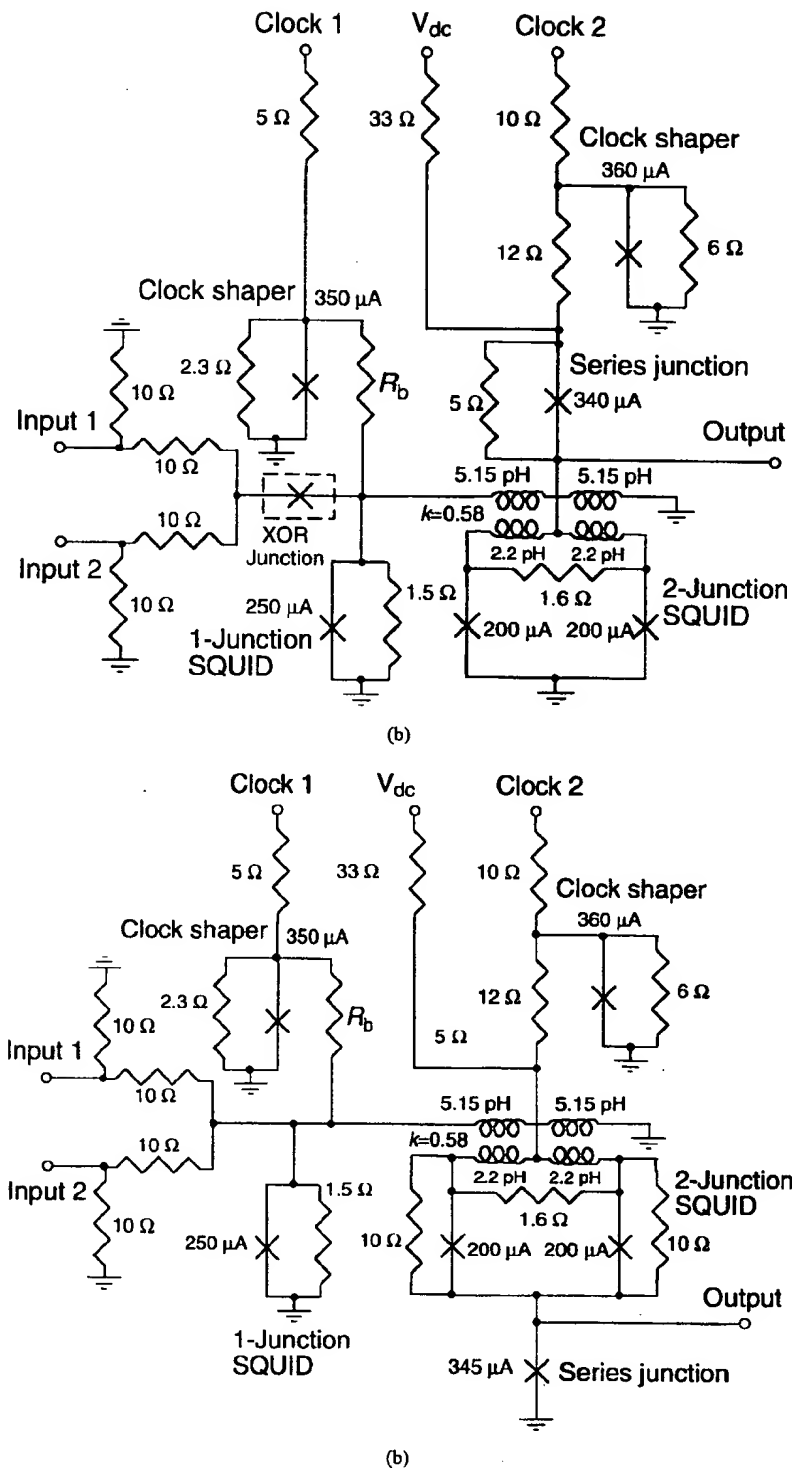


Fig. 1. Schematic diagrams of: (a) COSL OR/AND gate and (b) NOR/NAND gate.

phases applied through the clock shaping junctions. These junctions have the effect of clamping the SQUID biases at 2.5 mV when the clocks are applied, independent of the process variations.

The operation of the OR gate is understood intuitively as follows. When clock 1 is applied, an input to the gate greater

than $60\ \mu A$ is sufficient to fire the one-junction SQUID. Switching the one-junction SQUID causes a relatively large current to flow in the inductor, which is coupled to the output two-junction SQUID loop. The one-junction SQUID current suppresses the critical current of the two-junction SQUID so that when clock 2 is applied, the two-junction SQUID will

switch, giving 1 mV at the output, which produces 200 μ A in a 5- Ω load.

Note that there is a Josephson junction in series with the two-junction SQUID. Parameters are chosen such that the critical current of the series junction is less than the unmodulated two-junction SQUID and greater than the modulated two-junction SQUID. Therefore, when there is an input so the two-junction SQUID is fired, the SQUID becomes an effective high impedance and the series junction cannot fire. Conversely, if there is no input to the gate when clock 2 is applied, the series junction switches before the two-junction SQUID. Once it has switched, the series junction becomes an effective high impedance, preventing the two-junction SQUID from switching; in this case there is no output from the gate. The gate is termed complementary since for high output the two-junction SQUID is switched and not the series junction, and vice versa.

The NOR gate in Fig. 1(b) is similar to the OR gate with the exception that the position of the output series junction and the two-junction SQUID are interchanged. Therefore, the one-junction SQUID firing has the opposite effect. When clock 2 is applied, and the critical current of the two-junction SQUID is suppressed due to the one-junction SQUID input, the two-junction SQUID switches. The two-junction SQUID becomes an effective high impedance so that there is not enough current to activate the series junction; the output from the gate is clamped at zero. Conversely, if there is no input to the gate, since the critical current of the unbiased two-junction SQUID is greater than that of the series junction, the latter switches before the SQUID and prevents it from switching. This corresponds to a high output of 1 mV into a 5- Ω load.

The AND/NAND gates are derived from the OR/NOR gates by changing the resistance R_b of the clock supply for the one-junction SQUID. For the OR/NOR gates $R_b = 8.8 \Omega$ and for the AND/NAND gates $R_b = 14.3 \Omega$. Increasing R_b reduces the amount of current supplied by clock 1 so that two inputs are required to switch the one-junction SQUID input stage. The gates in Fig. 1 were designed so that there is a fan-out of two, where the output from each gate is typically 200 μ A. Larger fan-out is possible but would require different parameters in the output stage.

The XOR function is derived from the OR/AND gate by placing a 300- μ A junction in series with the input to the one-junction SQUID and setting $R_b = 9.8 \Omega$. The XOR requires that two OR/AND gates directly drive the input so that there is a fan-in of one. A single gate input of 200 μ A will not switch the 300- μ A XOR junction and, similar to the OR gate, the one-junction SQUID will switch, leading to a high output from the gate. However, if two inputs are simultaneously input, then the combined 400 μ A will fire the XOR junction. This, in turn, will reduce the input current so that, when clock 1 is applied, there will not be enough current input to activate the one-junction SQUID. Note that for correct operation, the XOR requires different clock phases than the other COSL gates. The optimal clocking scheme for the COSL circuits is described in Sections IV and V.

III. PROCESS VARIATIONS AND MONTE CARLO OPTIMIZATION

Process variations are important factors in the design of superconducting circuits. The fabrication process for superconducting circuits includes many factors that contribute to variations in parameter values. Since circuits are designed for specific nominal parameter values, variations in individual parameters can prevent them from working correctly. In the present work we focus on the variation of parameters which are typically used in the design and simulation of digital superconducting circuits; these are resistance, critical current, and inductance. We anticipate that variations in these three parameters will have the most significant effect on circuit operation. Other variable factors, such as leakage current, are neglected. Variations in resistance, critical current, and inductance may result from the contribution of many factors including photolithography variations, point defects, and film deposition inhomogeneity [5], [6]. We categorize process variations into two main groups: global and local.

Global variations are the average differences in a parameter between chips. For example, if a process targets 1 Ω/\square sheet resistance, and the average sheet resistance measured from several resistors distributed across a chip is 1.1 Ω/\square , then there is a 10% global deviation in that chip. The three important parameters (resistance, critical current, and inductance) will all have independent chip-to-chip global variations. Also note that different chips will have different average deviations, whether from the same wafer or different wafers. However, in the present work we *approximate* the global chip-to-chip parameter variations for all chips from the same wafer, from measurements of the average global parameter variations of the wafer.

Local variations are those between components in the same chip or circuit and are in addition to global variations. As an example, consider a chip with a critical current density targeting 1 kA/cm² that has a measured global critical current density of 1100 A/cm². If a single junction on a chip having a 200- μ A nominal critical current value is measured to have a critical current of 230 μ A, then it has a local variation of 5% in addition to a 10% global variation.

In order to relate the Monte Carlo simulations to experiments, we analyze the process variations in the HYPRES 1 kA/cm² fabrication process [13]. HYPRES measures the average critical current density for 12 junctions ranging from 3 \times 3 μ m² to 8 \times 8 μ m² in size on each wafer, and resistance values are obtained from the average of two 10 \times 50 μ m² resistors on each wafer [14]. These average critical current density and resistance values are reported with the final fabricated chips. HYPRES therefore gives the average global variation for each wafer.

The HYPRES design rule specification for global critical current density J_c is 30–5000 A/cm² \pm 15% and resistance R is 1 $\Omega/\square \pm$ 20% [14]. Chips with measured J_c and R within these design rule specifications are said to be within-specification, or “in-spec.” HYPRES ships at least one in-spec chip along with a data sheet for that chip for each foundry run. As a favor to its customers HYPRES may also, at its discretion, ship other chips and specification sheets which may or may not meet the

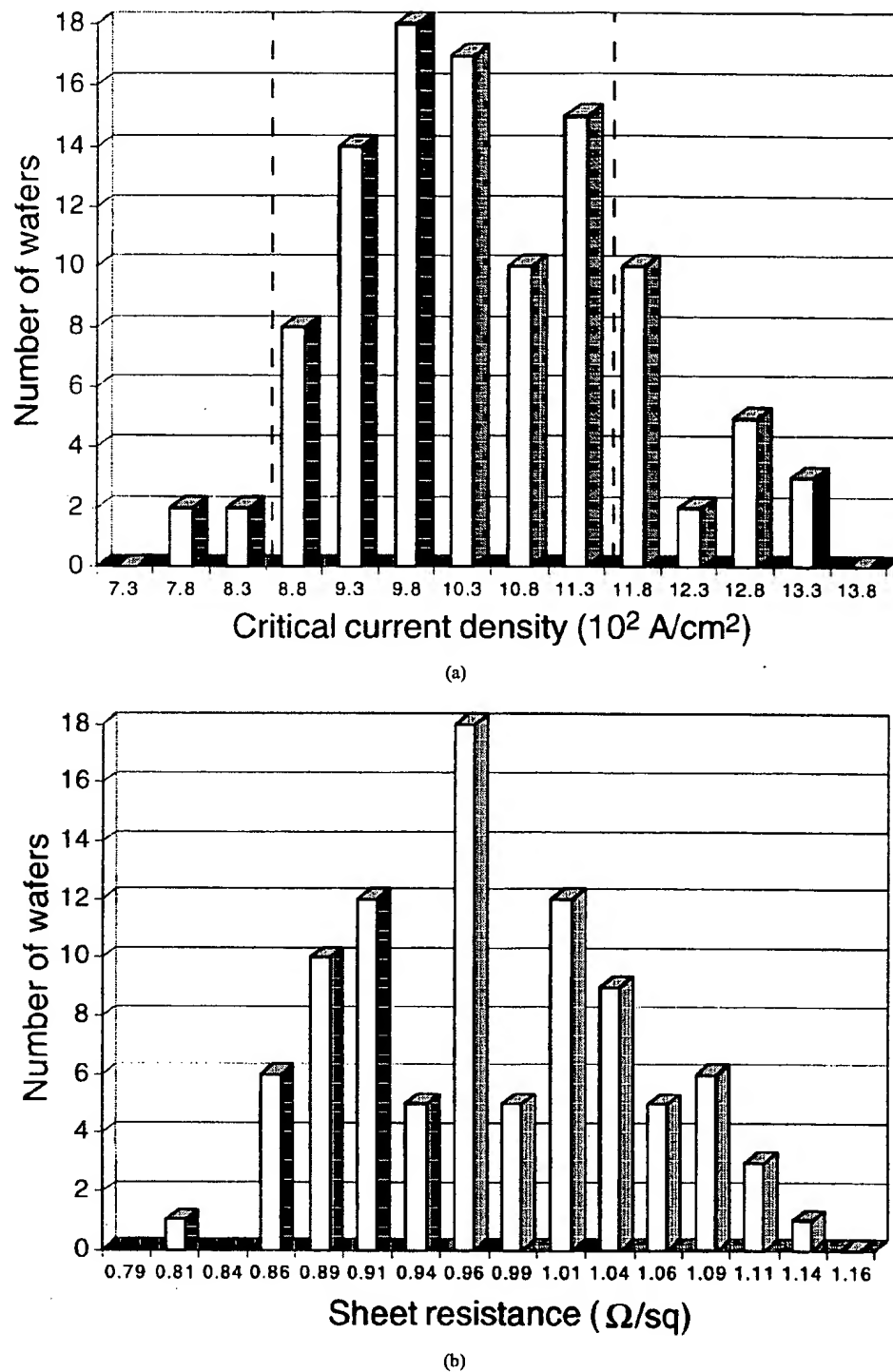
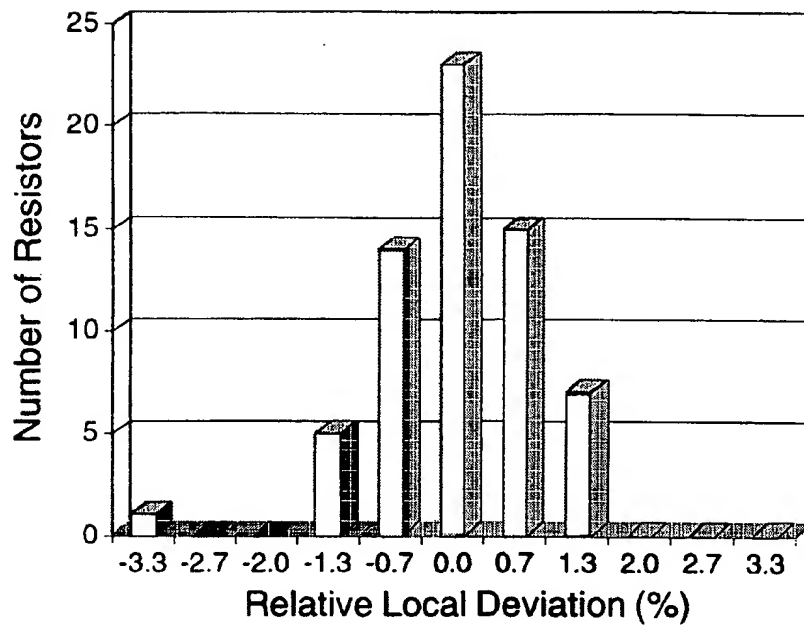


Fig. 2. Measured process variations in: (a) global critical current density and (b) global sheet resistance.

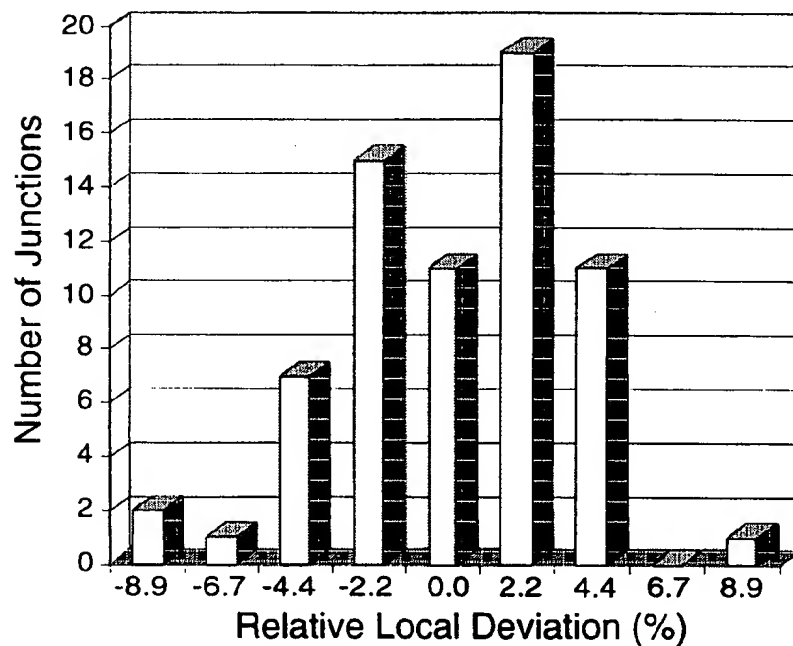
foundry specification. According to HYPRES, the additional chips or data on the corresponding specification sheets should not be construed to be indicative of the process variations for qualified in-spec chips [15].

Fig. 2(a) and (b) shows bar graphs of the tabulated HYPRES global variation data in resistance and critical current density. These data are compiled from the measured values reported by

HYPRES for chips purchased by the University of Rochester; average measurements of resistance for 95 wafers and average critical current density measurements for 106 wafers are given in the bar graphs. These data include both in-spec and out-of-spec chips shipped by HYPRES. The target resistance is $1 \Omega/\square$ and critical current density is 1000 A/cm^2 . The dashed lines in Fig. 2(a) signify the range of in-spec chips defined



(c)



(d)

Fig. 2. (Continued.) Measured process variations in (c) local variations in resistance and (d) local variations in critical current density. The dashed lines in (a) signify the range of qualified chips within the J_c design rule, and all nonzero data points in (b) are within specification. The local variation data (c) and (d) includes only in-specification chips. (Global data values (a) and (b) courtesy of M. Feldman and D. K. Brock.)

by the HYPRES J_c design rule. All of the resistance data in Fig. 2(b) are within the HYPRES resistance specification. From these data the standard deviation of resistance is $\sigma = 7.8\%$ with average $0.953 \Omega/\square$. For critical current density $\sigma = 12.5\%$ and the average is 1038 A/cm^2 .

In an attempt to quantify local variations, we have designed chips with identical resistors and Josephson junctions distributed approximately uniformly across the chip. Five

resistance and five Josephson junction chips were fabricated by HYPRES, and all five chips received by the University of California, Berkeley, were within the HYPRES J_c and R specification. Each resistance chip contained 13 nominal $5\text{-}\Omega$ resistors, and the Josephson junction chips contained 15 nominal $200\text{-}\mu\text{A}$ junctions. Each Josephson junction was surrounded by a $45 \times 81 \mu\text{m}^2$ moat to reduce flux trapping [4], and four-point measurements were made on all resistors

and Josephson junctions. Each of the five chips were from different wafers, and the individual component measurements were combined to obtain good statistics. The relative local deviations in resistance ΔR and critical current Δi_c for each component were calculated from

$$\Delta i_c = \frac{i_c - \langle i_c \rangle}{\langle i_c \rangle} \quad \text{and} \quad \Delta R = \frac{R - \langle R \rangle}{\langle R \rangle} \quad (1)$$

where i_c is the critical current of the individual junction and $\langle i_c \rangle$ is the average critical current of the components on a single chip. Similarly, R is the individual component resistance and $\langle R \rangle$ is the average resistance of all resistors on a chip. We therefore calculated the local variation for each component on a chip relative to the measured average value.

Fig. 2(c) and (d) shows the distribution of local resistance and critical current variations. The standard deviation of the resistance measurements is $\sigma = 0.82\%$, and the local critical current variations are more broadly distributed with $\sigma = 3.7\%$. The average measured Josephson junction critical current was $186 \mu\text{A}$, and the average resistance was 4.6Ω . Note that these data sets are small, and therefore our Gaussian statistics must be considered an approximation. Furthermore, since the local variation data are taken from only one HYPRES run, these data are not necessarily indicative of the general HYPRES process. However, for the simulations described in this paper, we will use these experimental data as an approximation to the local process variations.

In the present work we do not explicitly analyze measured inductance variations. Gaj and coworkers at the University of Rochester have estimated that global inductance deviations in the HYPRES process have an $8.5\% 3\sigma$ [16]. This result is an approximation obtained from numerical simulations using estimates of the process deviations in layer thickness and spacing. Polonsky at the State University of New York has measured global inductance variations in the HYPRES process, and he found that the deviations are within the HYPRES specifications on metal and insulator thickness variations. He reports on-chip, or local, variations well within 5% [17]. In the present work we approximate the worst case global and local inductance deviations by $15\% 3\sigma$ and $5\% 3\sigma$, respectively.

The local variation data in Fig. 2 has a $3\sigma = 11\%$ and $3\sigma = 2.5\%$ for critical current and resistance, respectively. Similarly, the standard deviations calculated from the global variation data in Fig. 2 give $3\sigma = 37\%$ for critical current and $3\sigma = 23\%$ for resistance. However, these global variation statistics do not accurately model the HYPRES process because HYPRES selects qualified, or in-specification, chips and therefore cuts off all variations greater than $\pm 15\% J_c$ and $\pm 20\% R$. In the present work, when we calculate theoretical yields with the “measured” statistics, we use the 3σ values calculated from the total global data in Fig. 2. Our simulation results with the measured statistics are therefore conservative and do not accurately describe qualified chips selected by HYPRES. Specifically for qualified chips with global variations within the HYPRES specification, the total parameter deviations including local variations can be as much as $\pm 26\%$ for J_c and $\pm 22\%$ for R . For these approximate data, we see

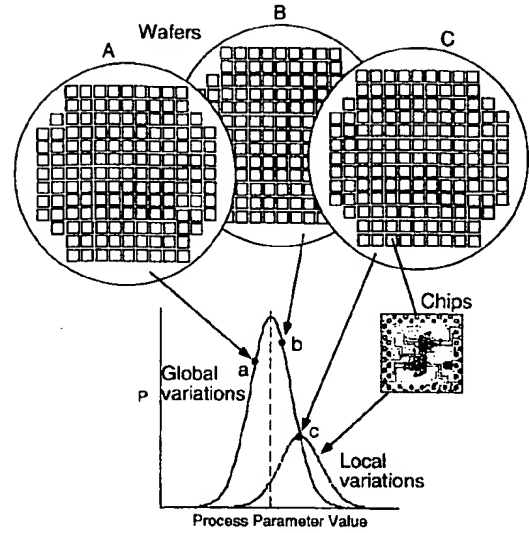


Fig. 3. Schematic of global and local process variations used in Monte Carlo optimization. Each chip has a global deviation; we approximate the chip-to-chip global variations using the wafer-to-wafer Gaussian distributions [Fig. 2(a) and (b)]. In addition to global variations, components fabricated on the same chip have different local variations which are also Gaussian distributed. These local variations are in addition to the global variations, shown schematically for the wafer C. The process deviations on a single chip are therefore described statistically by the multiplication of the global and local Gaussian distribution functions.

that the actual parameter values of many individual junctions and resistors can vary significantly from their nominal values.

We have therefore designed the COSL circuits specifically including process variations. The simulations include both local and global variations, shown schematically in Fig. 3. In the simulations each nominal value of resistance, critical current density, and inductance (R , J_c , and L) is multiplied by Gaussian-distributed random numbers. For global variations all resistors, junction critical currents, and inductances are multiplied by different random factors. The R , J_c , and L for an entire circuit are therefore shifted by different Gaussian distributed global variations. Each component on a chip also has local variations, and these variations are in addition to the global variations. We model the local variations by a second Gaussian superimposed on the global variation distribution, Fig. 3.

A Monte Carlo simulation run including both global and local variations is implemented in HSPICE [18] as follows. At the beginning of each iteration all R , J_c , and L values are multiplied by their respective uniform deviations from the nominal values. As a second step, local variations are included by multiplying each individual component by different Gaussian distributed random numbers. The individual component values are therefore varied at random around the global parameter values. Specifically for the Josephson junctions, the local variation in critical current is included by multiplying the area A of the junction by a Gaussian-distributed random number where σ is the local variation in critical current. We are thus making the assumption that the local variations in junction critical current are entirely the result of area variations. The Josephson model used in the HSPICE simulations is listed in the Appendix.

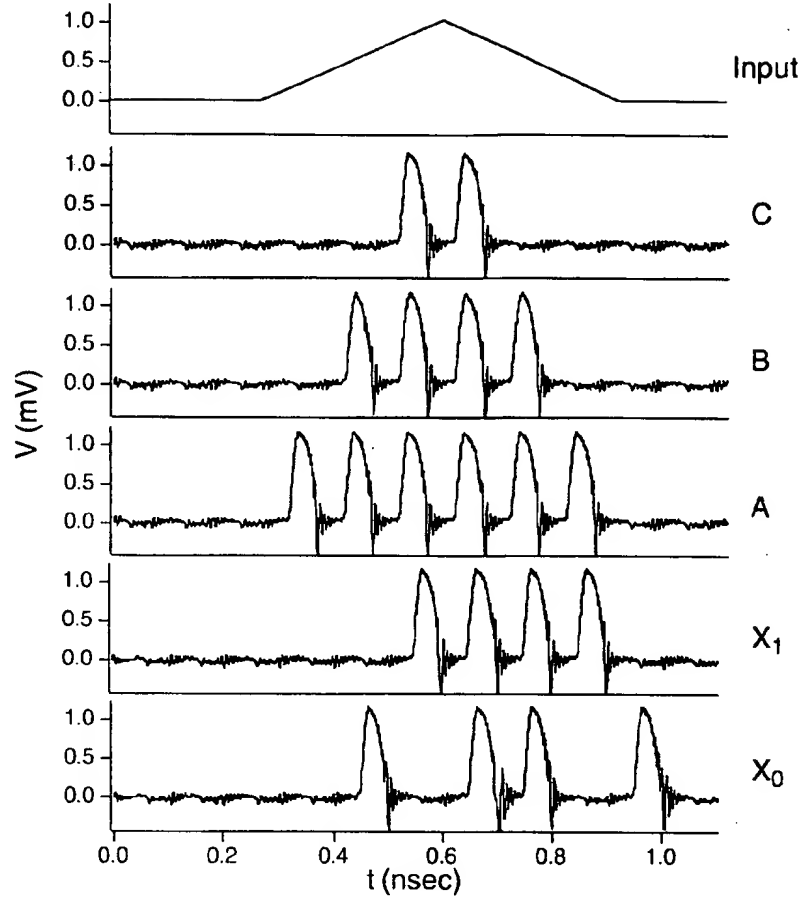


Fig. 5. 2-bit encoder simulated at 10 Gb/s. The input, shown on top, has been included to demonstrate the full flash ADC.

If A, B and C are the three low-to-high nonzero comparator inputs, then the two binary outputs X_0 and X_1 are given by the following Boolean expressions:

$$X_1 = B \quad (2)$$

$$X_0 = A\bar{B} + C = A \oplus B + C \quad (3)$$

where \oplus denotes the XOR function. The latter expression in (3) is true due to redundancies in the Karnaugh map [24] with thermometer code inputs. Fig. 4(a) and (b) shows two functionally equivalent schematic diagrams of the logic functions (2) and (3). MVTL is easiest to implement using the logic in Fig. 4(a) whereas COSL gives optimal yields using the logic in Fig. 4(b). The full gate layout of the COSL 2-bit encoder including the clock phases is shown in Fig. 4(c). The gates operate using three phase sinusoidal clocks, and the two-clock phases for each gate are labeled in the figure. These clocks (denoted by 1–3) are all 10 mV in amplitude and differ in phase by 120° . Note that even though there are only two gates in the actual logic function, nine gates are necessary for correct phasing of the data and clocks. The additional gates are OR and XOR buffers.

Simulation results for the 2-bit encoder in Fig. 4(c) are shown in Fig. 5 with 10-GHz sinusoidal three-phase clocks. The simulation assumes a ramped low-frequency input and the encoder counts the number of comparator levels. For

example, when only one comparator is switched the output is binary 01, two comparator inputs give 10 output, and three high inputs correspond to binary 11 output.

For flash ADC applications, the next level of complexity is a 3-bit encoder circuit. In this case there are seven comparator inputs, low-to-high values denoted by (A, B, C, D, E, F, G), and zero which are encoded onto three binary bits (X_0, X_1, X_2). The corresponding logic functions are

$$X_2 = D \quad (4)$$

$$X_1 = \bar{D}B + DF \quad (5)$$

$$= \bar{D} + \bar{B} + \bar{D} + \bar{F} \quad (6)$$

$$X_0 = \bar{D}(A \oplus B + C) + D(\bar{D} \oplus E + F) + G \quad (7)$$

$$= D + \bar{A} \oplus \bar{B} + \bar{C} + \bar{D} + D \oplus E + F + G. \quad (8)$$

The expressions (6) and (8) in X_1 and X_0 result from DeMorgan's theorem [24]. The logic functions (5) and (7) are easiest to implement using COSL OR/AND/XOR logic gates, whereas (6) and (8) are applicable to OR/NOR/XOR gate implementations.

Fig. 6(a) is the block diagram of the 3-bit encoder logic implemented using OR, AND, and XOR gates. Note that in this case we implement the inversion function using an XOR gate with one of the inputs pulsed constantly high. The pulser is just an OR gate with no inputs and $R_b = 6 \Omega$.

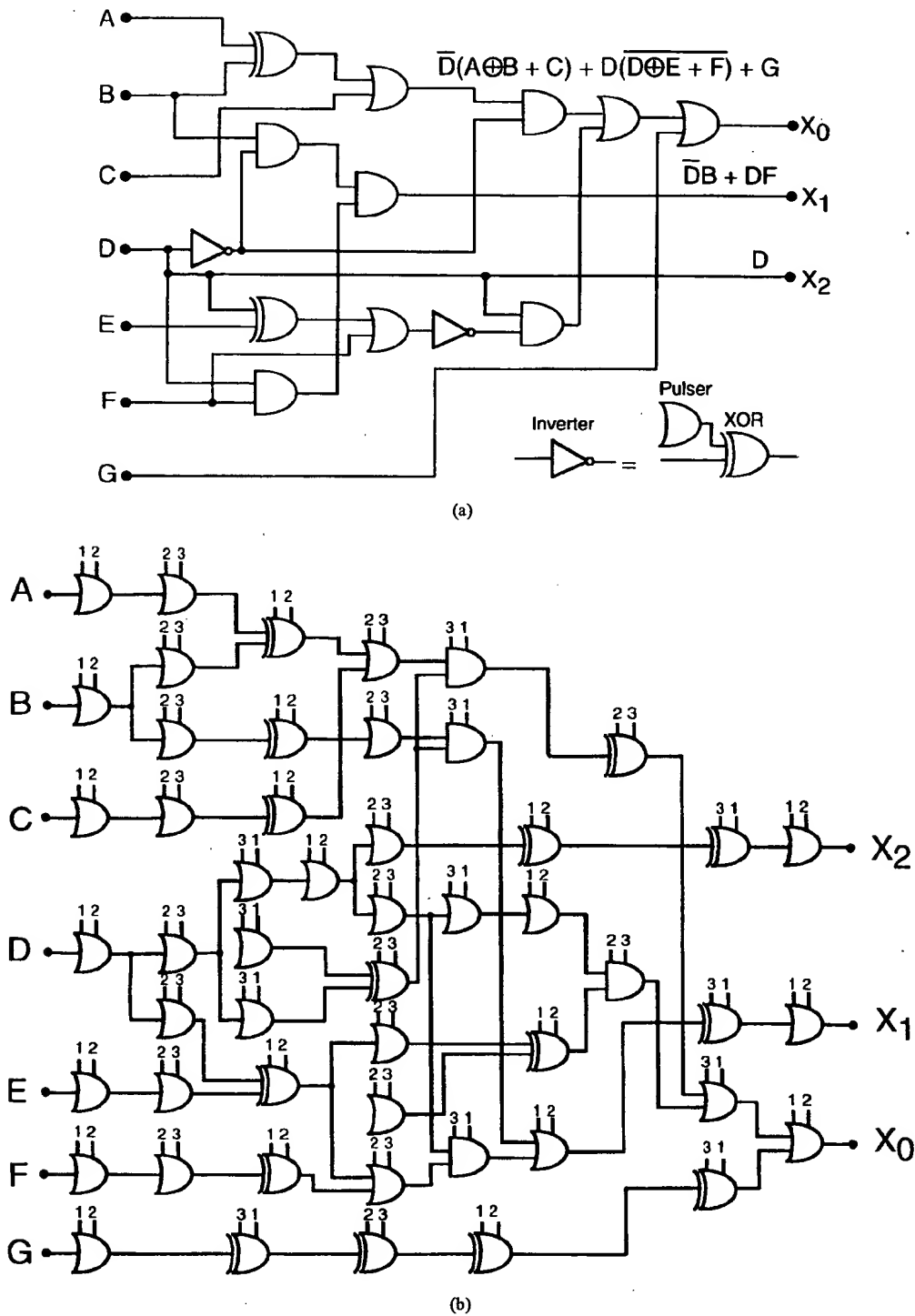


Fig. 6. 3-bit encoder ADC logic. (a) XOR/OR/AND logic implementation and (b) COSL gate layout with three-phase clock including buffers.

The complete gate layout for the 3-bit encoder logic is shown schematically in Fig. 6(b), including the clock phasing labeled (1-3) on top of each gate. Simulation results for the 3-bit encoder in Fig. 6(b) are given in Fig. 7. The thermometer code in Fig. 7(a) corresponds to a ramped input, and the output is the input encoded on the three binary bits.

We simulated many possible configurations of 2- and 3-bit encoders (not shown). The gate configurations in Fig. 4(c)

and Fig. 6(b) are the final result of the optimization process. For optimal yield we found that the gates require a special clocking scheme. Specifically, the inputs of all OR/AND gates have the same clock as the preceding gate output. This is shown schematically in Fig. 4(c) and Fig. 6(b). However, due to the novel operation of the XOR gate, described previously in Section II, the XOR input must have a clock phase different from the previous gates' outputs. As an example, see Fig. 4(c).

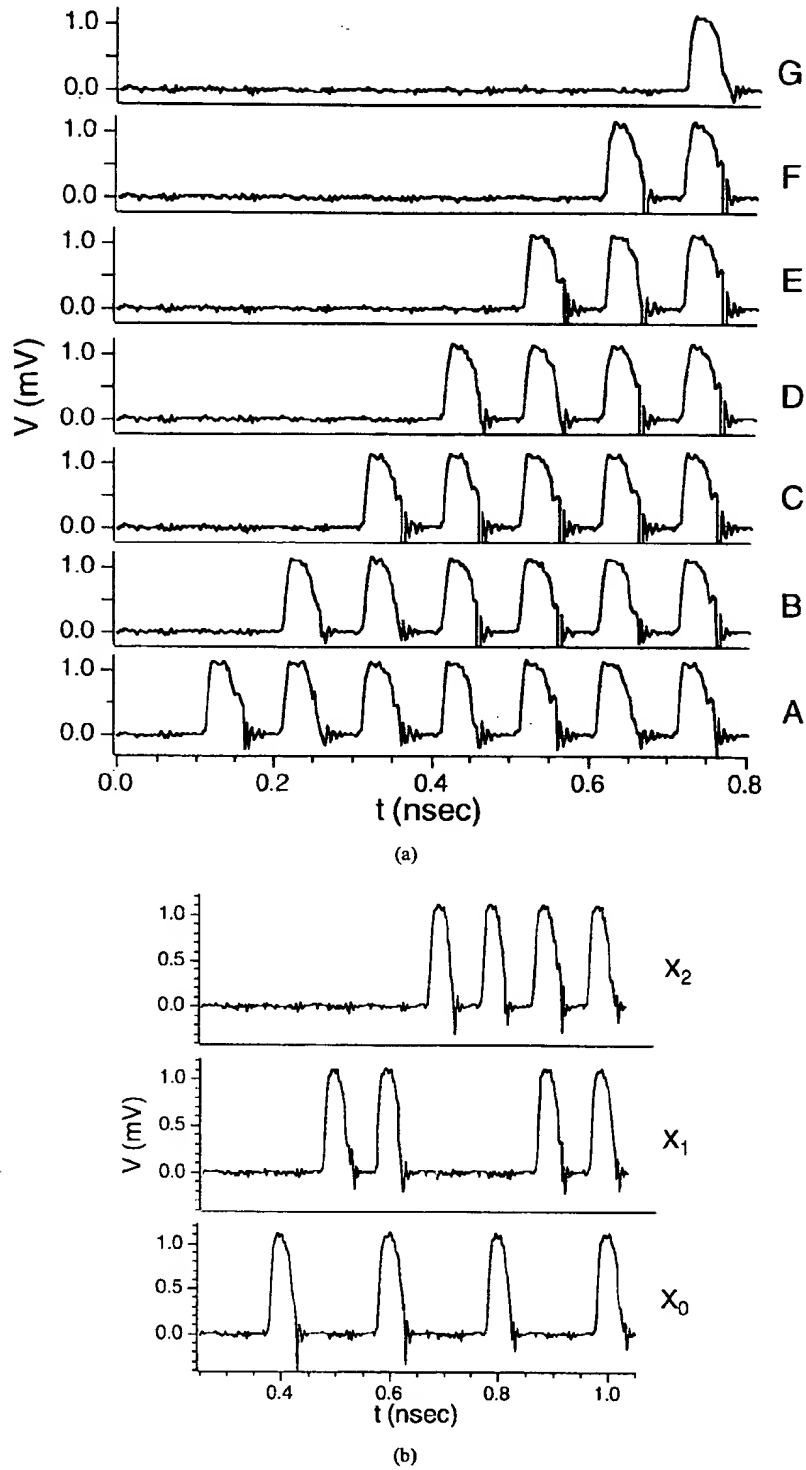


Fig. 7. 3-bit encoder simulation results at 10 Gb/s: (a) inputs and (b) three-output bits.

Note in Fig. 4(c) that the last two OR gates have the same clock 1 input as the XOR gates' outputs, and that the XOR gates have an input clock 3 which follows the OR gate buffer clock 2 output. Furthermore, to eliminate switching errors for the one-junction SQUID input stage, when connecting gates we use $10\text{-}\Omega$ resistive matching networks (see Fig. 1) to reduce the current input to the gate when there is a fan-in of two. A

$5\text{-}\Omega$ series resistor is used for direct coupling, fan-in of one, of all logic gates.

We have simulated both the 2- and 3-bit encoder circuits repeatedly using several gate configurations and different global and local process parameter spreads. Fig. 8 shows the final Monte Carlo results for the 2-bit encoder with 5- and 10-GHz sinusoidal clocks and the 3-bit encoder with 10-GHz

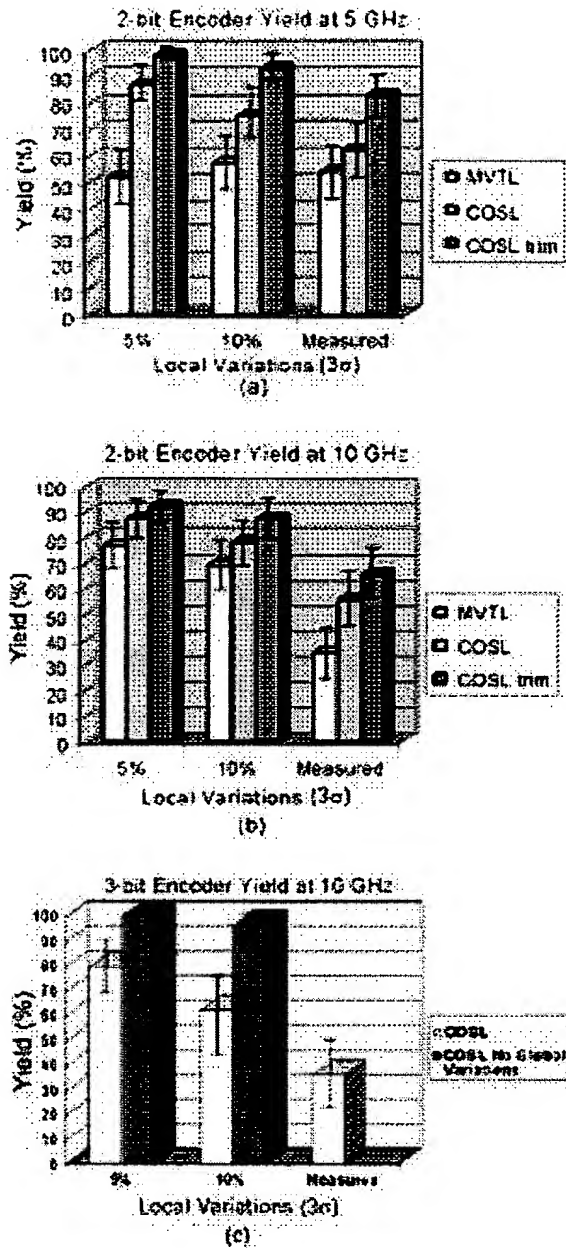


Fig. 8. (a) Simulated theoretical yields for the 2-bit encoder operating at 5 Gb/s. In the plot the first two data sets are for artificial global variations and 5 and 10% 3σ local process variations. The third set of data is theoretical yield calculated using the measured process variations. (b) The same as (a) except the clocks are 10 GHz. (c) 3-bit encoder Monte Carlo simulation results at 10 GHz with artificial global variations and 5 and 10% 3σ local process parameter spreads and measured parameter spreads. Yield results are also shown for 5 and 10% local variations with zero global variations.

clocks. The 2-bit encoder simulations are for 100 Monte Carlo cycles, and the 3-bit simulations are for 50 Monte Carlo cycles. In these plots the first two sets of data bars are for artificial global variations of $3\sigma = 15\%$ for R and L and $3\sigma = 10\%$ for J_c ; the first set of data bars have local variations of 5% 3σ on all parameters, and the second set of data bars have 10% 3σ local variations on all parameters. The third set of data bars are the results of simulations with the measured

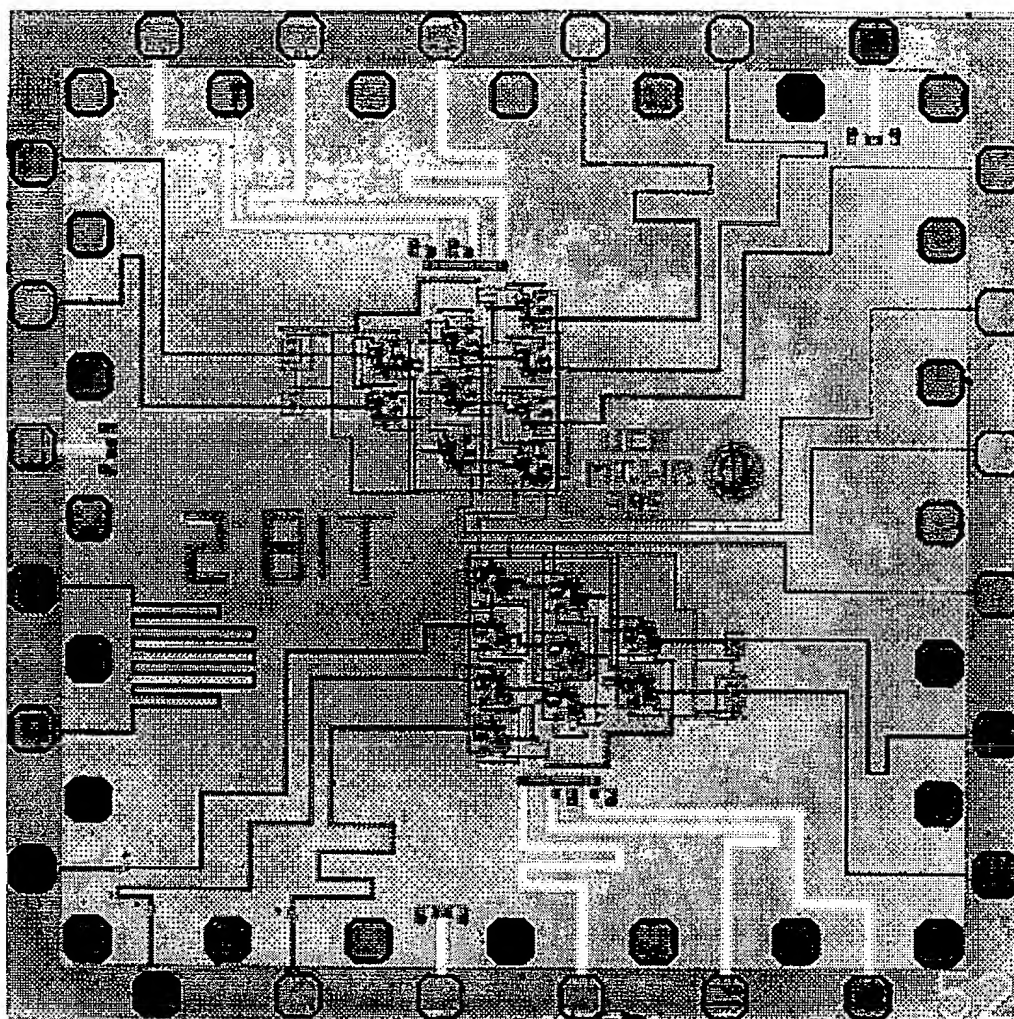
variations (Fig. 2); global variation $3\sigma = 37\%$ for J_c and $3\sigma = 23\%$ for R , and local variations have a $3\sigma = 11\%$ for J_c and $3\sigma = 2.5\%$ for R . For the simulations with measured variations we approximate the inductance variation as 15% 3σ globally, and 5% 3σ locally.

Note that all Monte Carlo simulation results have a statistical uncertainty which is a function of the number of trials and the calculated yield. The yield accuracy analysis is described in detail elsewhere [3], [19]. However, without going into the details of this analysis, it is useful to put the accuracy of Monte Carlo simulation results in perspective. A yield of 92% will have uncertainties of $\pm 7.7\%$ for 50 MC cycles, $\pm 5.4\%$ for 100 MC cycles, and $\pm 3.8\%$ for 200 MC cycles. A yield of 66%, on the other hand, will give uncertainties of $\pm 13.5\%$ for 50 MC cycles, $\pm 9.5\%$ for 100 MC cycles, and $\pm 6.7\%$ for 200 MC cycles. Therefore, simulations with low yields have larger uncertainties, and increasing the number of Monte Carlo cycles decreases the statistical uncertainty. The results of Fig. 8 are therefore not "exact" but describe the approximate theoretical yields of the circuits within a statistical error range. For clarity in Fig. 8 we have included error bars for the statistical uncertainty of each simulation result.

The results of the 2-bit encoder for 100 Monte Carlo cycles are given with and without dc bias trimming, and for an equivalent MVTL encoder. The MVTL gates used in the encoder were modified to give high yield at 10 GHz [3]. The yield of the COSL 2-bit encoder is dependent upon the local variations; at 10 GHz the yield is $87\% \pm 6.7\%$ with 5% local variations, and this drops to $78\% \pm 8.3\%$ with 10% local variations. However, the addition of dc bias trimming increases the yield to approximately $90\% \pm 5.4\%$ in both cases. We also calculated the theoretical yield of the 2-bit encoder implemented using MVTL gates. At 10 GHz with 5% 3σ local variations the MVTL yield was $77\% \pm 8.4\%$, and with 10% local variation the yield drops to approximately $69\% \pm 9.2\%$.

From the Monte Carlo simulations we found that even though the NOR/NAND inversion functions have a high theoretical yield individually, when the NOR/NAND gates are included in large circuits the yield of the system is significantly less than expected. At 10 GHz with 5% 3σ local variation the 3-bit encoder OR, NOR, and XOR implementation had a yield of approximately $45\% \pm 15\%$ in 50 Monte Carlo cycles (not shown in Fig. 8). However, the XOR function, which is almost identical to the OR/AND gate, has the same theoretical yield as the OR/AND gates. The theoretical yield of the 3-bit encoder, simulated for 50 Monte Carlo cycles, is shown in Fig. 8(c) using the XOR inversion architecture shown in Fig. 7(c). The theoretical yield with 5% local 3σ variations is $80\% \pm 11.3\%$ without trimming. When the local variations are increased to 10% 3σ the yield is $62\% \pm 13.7\%$. We therefore chose to implement an inversion function using the COSL XOR gate to give maximum yields for large circuits.

Note from Fig. 8(c) that, as expected, the yield of the 3-bit encoder decreases as the local variations are increased. Also, comparing 2- and 3-bit encoder circuits, large COSL circuits are more sensitive to the local variations than are small COSL circuits. Fig. 8(c) also shows the 3-bit encoder yield with zero global variations and no trimming; with 5% local variation the



(a)

Fig. 9. (a) 5 mm \times 5 mm 2-bit encoder chip fabricated using the HYPRES process.

theoretical yield is 100% and with 10% local variation, 96% (-5.4% , $+4\%$) in 50 Monte Carlo cycles. This is an important result, and it shows that decreasing the global variations is the most significant factor for increasing the theoretical yield.

Finally, we have calculated the 2- and 3-bit encoder yields using the measured process variations. At 10 GHz, the COSL 2-bit encoder yield was $56\% \pm 9.5\%$, and the 3-bit was $36\% \pm 13.6\%$. The 2-bit MVTL decoder had a yield of $35\% \pm 9.5\%$. With trimming the yield of the COSL 2-bit encoder increased to $66\% \pm 9.5\%$. Clearly, large global variations have a significant effect on the theoretical yield of the circuits.

Some of the uncertainty ranges, given by error bars in Fig. 8, overlap, and from a statistical standpoint it is not possible to draw firm conclusions comparing these specific cases. However, the data overlap is typically small occurring at the top and bottom of adjacent data uncertainty intervals so that one can see the trend in these data. Excessively long simulation times prevented us from calculating the theoretical yields for more Monte Carlo cycles, which would have in turn

reduced the uncertainties. However, note that at 5 and 10 GHz the COSL 2-bit encoder yield with trimming is better, in a strict statistical sense, than MVTL for all variations. Furthermore, at 10 GHz with measured variations the COSL yield without trimming is also significantly better, in a strict statistical sense, than MVTL. These data therefore clearly demonstrate that COSL gates have a higher probability of operating successfully in the frequency range of 5–10 GHz than MVTL.

The important point is that these simulations show that the fabrication process plays a significant role in successfully demonstrating working circuits. The Monte Carlo method enables one to evaluate the expected yield of a circuit with many different nominal parameters. Circuits are optimized by choosing parameters which maximize the theoretical yield not only of the component gates, but also of the entire circuit. The circuit yield therefore acts as a pretest evaluation of how well the circuit has been optimized and correlates directly with the probability of fabricating working circuits. Furthermore, the results in Fig. 8(c) with no global variations demonstrate that if the global variations of the parameter spreads can be

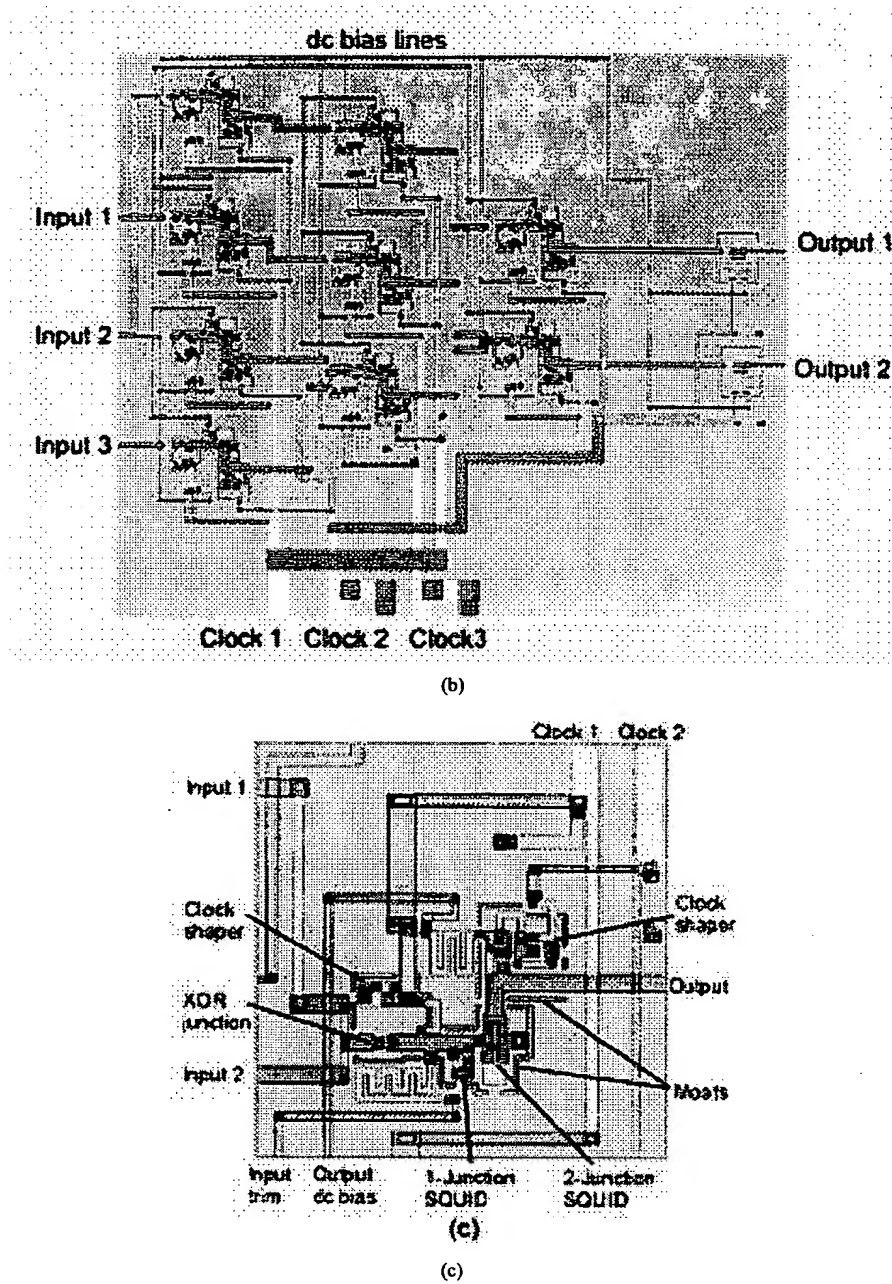


Fig. 9. (Continued.) (b) Expanded view of the 2-bit encoder (the area in the photograph is $1.3 \times 1.5 \text{ mm}^2$). (c) COSL XOR gate in the encoder layout (the area is $233 \times 245 \text{ } \mu\text{m}^2$).

minimized, possibly by choosing specific wafers [25], then the theoretical yield of complex superconducting circuits dramatically increases. Of course, decreasing the local parameter spreads also increases the yield of superconducting circuits.

V. CIRCUIT LAYOUT AND EXPERIMENTAL TEST RESULTS

We had COSL gates and 2-bit encoder circuits fabricated using the 1 kA/cm^2 HYPRES process. A photograph of the COSL 2-bit encoder $5 \text{ mm} \times 5\text{-mm}$ chip is shown in Fig. 9(a). The chip contains two 2-bit encoders. An expanded view of a single encoder is shown in Fig. 9(b), and one of the XOR

gates in Fig. 9(c). In Fig. 9(b) the three phase clocks are at the top, the three thermometer code inputs are on the left, the two binary outputs are on the right, and dc bias lines are on the bottom. The gate outputs are amplified to 2.5 mV for detection off-chip using single-junction output amplifiers shown on the right in Fig. 9(b).

Note that the Josephson junctions in the gate Fig. 9(c) are surrounded by moats, or holes in the ground plane. These holes enclose approximate areas of $60 \times 70 \text{ } \mu\text{m}^2$ and should shield the circuit for magnetic fields up to $\Phi_0/4 \cong 5 \text{ mG}$, where Φ_0 is the flux quantum $h/2e$ [4].

We have used Monte Carlo simulations to calculate the effect of impedance mismatches. We found from these simulations that if the clock lines and connections between gates are not impedance-matched, the yield of the circuits at 10 GHz is reduced. All of the transmission lines are therefore impedance-matched for the circuit in Fig. 9. The inputs and outputs of the gates are matched to $50\ \Omega$. The gate clock lines have impedances of $6.7\ \Omega$ (clock 1) and $13.4\ \Omega$ (clock 2), and these clock lines are combined into a matched tree that has a characteristic impedance of $1.6\ \Omega$ at the pad. Resistive matching networks are used for the inputs of the bottom 2-bit encoder Fig. 9(a).

Resistive matching networks are especially useful for broadband testing. However, since the superconductive circuits have an intrinsically low impedance, a large resistance is required to match to $50\ \Omega$. This resistor dissipates excessive power, and it is impractical to use resistive matching for the three phase clocks. To avoid excessive heating of the chip, we therefore mismatch the $1.6\text{-}\Omega$ clock lines at the pads in Fig. 9 to the $50\text{-}\Omega$ cables external to the chip. Since the clocks are sinusoids, a large reflected component in the coaxial cables does not effect the shape of the signal input to the chip.

Experimental test results are given for the 2-bit encoder operating at 1 Gb/s in Fig. 10. The 1-Gb/s inputs are generated using an HP 80000 data generator, and the sinusoidal clock is generated by an HP 85735 synthesizer signal generator. The inputs and outputs are observed on a Tektronix 11 801A digital sampling oscilloscope. The chip is mounted on the end of an American Cryoprobe high-speed probe [26] surrounded by two mumetal shields and immersed in a liquid helium dewar. The experimental data in Fig. 10 corresponds to the simulation in Fig. 5. The thermometer code inputs are the three top traces in Fig. 10, and the two binary output bits are the bottom two traces. The input and output data are shifted by approximately 15 ns; this is the time delay of the signal as it propagates in the cables from the chip. The 2.5-mV superconducting circuit outputs have been averaged for the photograph Fig. 10. However, no averaging is necessary if one uses a low-noise amplifier [27].

At low frequencies (5 kHz) it is straightforward to apply the nominal 10-mV clock amplitudes to the circuit; however, at 1 GHz the test setup is more complicated. All room temperature electronics has a characteristic impedance of $50\ \Omega$. The high-speed probe has $50\text{-}\Omega$ cables and is impedance mismatched to the $1.6\text{-}\Omega$ clock transmissions lines at the pads of the chip. For high-speed testing the clock amplitudes are measured using the $50\text{-}\Omega$ sampling scope before they are connected to the high-speed probe. We found that due to the impedance mismatch and loss in the cables, 400-mV clock amplitudes are required, measured by the $50\text{-}\Omega$ scope, to give the nominal 10-mV clock amplitudes at the chip.

Fig. 11 shows the same circuit clocked at 4 GHz. In this case we use the divide-by-four of an NEL NG4218 multiplexer to phase lock the clock with the HP 80000 data generator. The inputs in Fig. 11(a) are 1 Gb/s RZ and, since the circuit is clocked at 4 Gb/s, there are two pulses output in Fig. 11(b) for each input pulse. The large oscillation on the background is due to imperfect balancing of the three-phase clocks and can

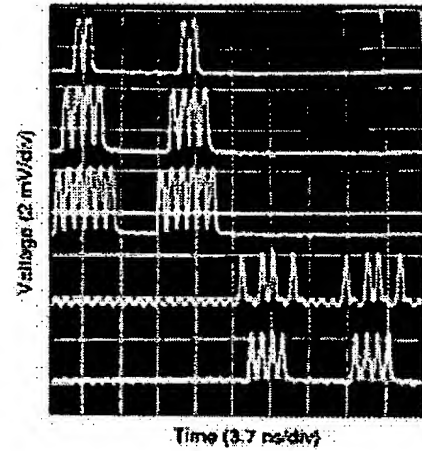


Fig. 10. 2-bit encoder operating at 1 Gb/s. The three inputs are shown at the top and the two output bits on the bottom.

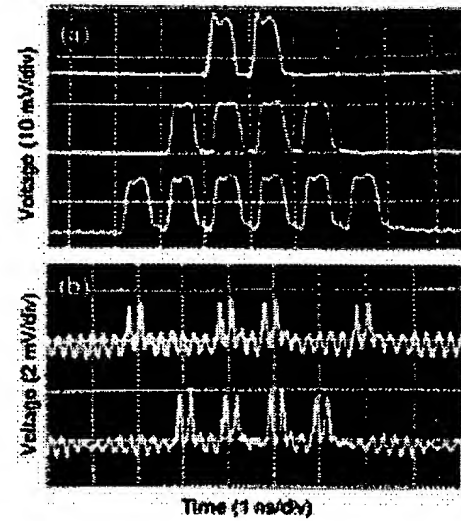


Fig. 11. 2-bit encoder clocked at 4 Gb/s with 1 Gb/s inputs. (a) The three inputs and (b) the two output bits.

be reduced significantly by the addition of a fourth clock phase [27]. We have thus far demonstrated the full 2-bit encoder at 5 Gb/s, with portions of the circuit operating up to 8 Gb/s. We have also demonstrated the basic COSL OR/AND gate at 10 Gb/s and measured bit error rates. These results are described in detail elsewhere [2], [27].

VI. SUMMARY AND CONCLUSIONS

Experimental data for global and local process variations have been presented. For Josephson superconducting circuits these process variations can significantly reduce the probability of obtaining working circuits at ultra-high speed. An optimization technique was described such that basic gates are optimized using the Monte Carlo method and then incorporated into larger circuits. We used the Monte Carlo method to simulate basic gates and complex circuits in order to realize logic functions with maximum yield.

We specifically optimized COSL gates and circuits for 5–10 GHz operation using the Monte Carlo method. After optimization the basic gates have a very high theoretical yield, approaching 100% in 50 Monte Carlo cycles at 10 GHz. With large global ($\geq 10\%$ 3σ) and local (10% 3σ) variations, COSL 2-bit encoder circuits have yields of $78\% \pm 8.3\%$ in 100 Monte Carlo cycles, and 3-bit encoders have yields of $62\% \pm 13.7\%$ in 50 Monte Carlo cycles. The addition of dc bias trimming to cancel global process variations increased the theoretical yield. With zero global variations and 10% 3σ local variations, the yield of complex 3-bit encoder circuits was $96\% \pm 5.5\%$ with no dc bias trimming. Compared to similar MVTL circuits, COSL logic has a significantly higher theoretical yield at 10 Gb/s. These results contrast the effects of global and local variations and increasing circuit complexity.

We also presented 1- and 4-Gb/s test results on COSL 2-bit encoder circuits. We discussed gate layouts, impedance matching, and optimal clock phasing. Basic COSL gates have been demonstrated at 10 Gb/s, and COSL 2-bit encoder circuits at 5–8 Gb/s. These results are described in detail elsewhere [2].

Monte Carlo optimization is relatively simple to implement and has the advantage that the calculated yields correlate directly with the probability of fabricating working circuits. Furthermore, our simulation results demonstrate quantitatively the effect of improving the process.

APPENDIX

HSPICE SUBCIRCUIT FOR A JOSEPHSON JUNCTION

The RSJ model is used to model the Josephson junction. It consists of a parallel connection of a basic Josephson junction, a voltage-dependent resistor, and the junction capacitance. The total Josephson current is given by

$$i_J = I_c \sin \varphi + \frac{v}{R_{\text{shunt}}} + C_{\text{shunt}} \frac{dv}{dt} \quad (9)$$

and the voltage across the junction as

$$v = \frac{\Phi_0}{2\pi} \frac{d\varphi}{dt} \quad (10)$$

The gauge invariant phase difference φ is generated in the model by taking (10) as the governing equation of a capacitor. The voltage v across the junction is monitored and converted to a current with the same magnitude. This current is fed to a series capacitor with a capacitance of $\Phi_0/2\pi$. The voltage across the capacitor is thus a representation of φ . The initial value of φ is easily implemented as the initial value of the voltage across the capacitor.

The magnitude of the critical current and the associated junction capacitance, normal resistance, and subgap resistance are calculated from an area factor, which is passed to the Josephson subcircuit. In the 1-kA/cm² HYPRES process, an area factor of 1 represents an area of 10 μm^2 and thus a critical current $I_c = 100 \mu\text{A}$. The HSPICE subcircuit description for

the 1-kA/cm² HYPRES process follows:

```
.subckt jj 2 4 area=1 ij=100u rn=26 rg=300
cj=0.4p jc=1 vg=2.6m dlv=0.3m phi=0
c1 2 4 c= 'cj*area' ctype=1
gr 2 4 vcr pwl(1) 2 4
+ '-1 * vg','rn/area'
+ '-1 * (vg - dlv)','rg/area'
+ 'vg - dlv','rg/area'
+ 'vg','rn/area'
gjos 2 4 cur='ij*area*sin(v(3,4)*10k)'
gphi 4 3 cur='v(2,4)'
rphi 4 3 1000g
cphi 3 4 3.291 090p ic='phi'
.ends jj
```

The capacitor cphi was scaled by a factor of 10 000 to increase numerical stability and accuracy during simulations. This factor is also reflected in the expression for gjos.

Note that we make no warranties, expressed or implied, that the above subroutine is free of errors. The authors disclaim any liability for direct or consequential damages resulting from the use of this subroutine.

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